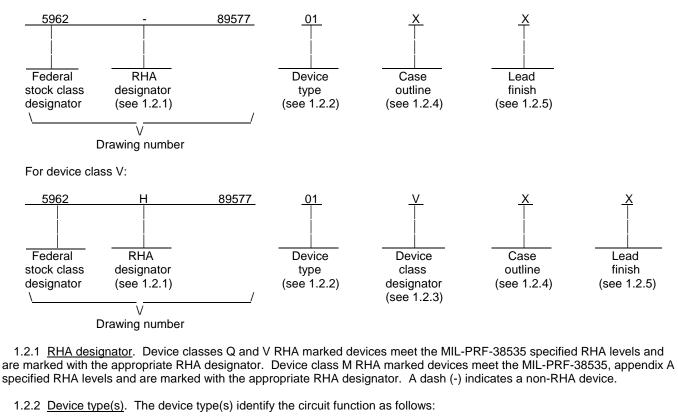
|  |   |  |                    |  |   |  |  | I                       | REVISI             | ONS  |  |  |  |   |   |                                       |  |                                  |                     |         |
|--|---|--|--------------------|--|---|--|--|-------------------------|--------------------|--|--|--|--|---|---|---------------------------------------|--|----------------------------------|---------------------|---------|
| LTR  |   |  |                    |  | [   | DESCF  | RIPTIO   | N                       |                    |  |  |  | DATE (YR-MO-DA)  |   |   | DA)                                   | APPROVED   |                                  |                     |         |
| А  | Char  | Changes in accordance with NOR 5962-R043-92  |                    |  |   |  |  |                         | 91-11-25           |  | M. L. Poelking                                     |  |  |   |   |                                       |  |                                  |                     |         |
| В  | Char  | nges in  | accord             | ance w   | ith NO  | R 5962   | -R070-   | -93                     |                    |  |  | 93-01-22   |  | M. L. Poelking  |   |                                       |  |                                  |                     |         |
| С  | Char  | nge to c   | lass le            | vel V. L   | Jpdate  | boilerp  | late I   | LTG                     |                    |  |  |  |  | 97-0  | )7-11   |                                       | Т. М   | . Hess                           |                     |         |
| D  | Char  | nges in  | accord             | ance w   | ith NO  | R 5962   | -R001-   | -98                     |                    |  |  |  |  | 97-1  | 0-17  |                                       | M. L   | . Poelk                          | ing                 |         |
| E  | Made  | e Rad H  | lard ch            | anges  | in Tabl   | e I. Ado   | ded ap   | pendix                  | A LT(              | G  |  |  |  | 99-0  | 9-08  |                                       | M. L   | M. L. Poelking                   |                     |         |
| F  | Upda  | ate boile  | erplate            | to MIL-  | PRF-3   | 8535 re  | equiren  | nents                   | - LTG              |  |  |  |  | 01-0  | 4-25  |                                       | Thomas M. Hess   |                                  |                     |         |
| G  | Adde  | ed tests   | V <sub>OL2</sub> a | nd V <sub>OH2</sub>  | to tabl   | le I she   | et 6. –  | LTG                     |                    |  |  |  |  | 01-1  | 2-21  |                                       | Thor   | Thomas M. Hess                   |                     |         |
| Н  |   |  |                    |  |   |  |  | s to nar<br>able I.     |                    | nds for                                    | the  |  |  | 02-0  | )7-23   |                                       | Thor   | nas M.                           | Hess                |         |
|  |   |  |                    |  |   |  |  |                         |                    |  |  |  |  |   |   |                                       |  |                                  |                     |         |
| REV<br>SHEET   | G<br>35   | G<br>36  | G<br>37            | G<br>38  | G<br>39   | G<br>40  | G<br>41  | G<br>42                 | G<br>43            | G<br>44                                    | G<br>45  | G<br>46  | G<br>47  | G<br>48   |   |                                       |  |                                  |                     |         |
|  |   |  |                    |  |   |  |  |                         |                    |  |  |  |  |   | E   | F                                     | С  | G                                | G                   | G       |
| SHEET  | 35  | 36   | 37                 | 38   | 39  | 40   | 41   | 42                      | 43                 | 44   | 45   | 46   | 47   | 48  | E<br>29   | F<br>30                               | C<br>31  | G<br>32                          | G<br>33             | G<br>34 |
| SHEET<br>REV   | 35<br>C<br>15   | 36<br>C  | 37<br>C            | 38<br>C  | 39<br>C<br>19   | 40<br>C  | 41<br>E<br>21                                      | 42<br>E<br>22           | 43<br>C            | 44<br>C                                    | 45<br>E  | 46<br>C  | 47<br>F  | 48<br>E   |   | 30                                    |  | -                                | 33                  |         |
| SHEET<br>REV<br>SHEET  | 35<br>C<br>15<br>S  | 36<br>C  | 37<br>C            | 38<br>C<br>18<br>REV   | 39<br>C<br>19   | 40<br>C  | 41<br>E<br>21<br>H                                 | 42<br>E<br>22<br>C      | 43<br>C<br>23<br>E | 44<br>C<br>24                              | 45<br>E<br>25<br>F                                 | 46<br>C<br>26<br>G                                 | 47<br>F<br>27<br>E                                     | 48<br>E<br>28<br>E  | 29<br>E   | 30<br>H                               | 31<br>E  | 32<br>C                          | 33<br>C             | 34<br>C |
| SHEET<br>REV<br>SHEET<br>REV STATU   | 35<br>C<br>15<br>S  | 36<br>C  | 37<br>C            | 38<br>C<br>18<br>REV<br>SHE<br>PRE                               | 39<br>C<br>19   | 40<br>C<br>20<br>DBY   | 41<br>E<br>21<br>H<br>1                            | 42<br>E<br>22           | 43<br>C<br>23      | 44<br>C<br>24<br>F                         | 45<br>E<br>25<br>F<br>5                            | 46<br>C<br>26                                      | 47<br>F<br>27<br>E<br>7                                | 48<br>E<br>28<br>E<br>8   | 29<br>E<br>9                                    | 30<br>H<br>10                         | 31<br>E<br>11  | 32<br>C<br>12                    | 33<br>C<br>13       | 34      |
| SHEET<br>REV<br>SHEET<br>REV STATU<br>OF SHEETS<br>PMIC N/A  | 35<br>C<br>15<br>S  | 36<br>C<br>16<br>20<br>20  | 37<br>C            | 38<br>C<br>18<br>REV<br>SHE<br>PRE<br>Chr                        | 39<br>C<br>19<br>ET   | 40<br>C<br>20<br>D BY<br>er A. Ra<br>BY  | 41<br>E<br>21<br>H<br>1                            | 42<br>E<br>22<br>C      | 43<br>C<br>23<br>E | 44<br>C<br>24<br>F                         | 45<br>E<br>25<br>F<br>5                            | 46<br>C<br>26<br>G<br>6                            | 47<br>F<br>27<br>E<br>7<br>SE S<br>COL                 | 48<br>E<br>28<br>E<br>8   | 29<br>E<br>9<br>Y CE<br>JS, O                   | 30<br>H<br>10<br>NTEF                 | 31<br>E<br>11<br>COL<br>43216                          | 32<br>C<br>12                    | 33<br>C<br>13       | 34<br>C |
| SHEET<br>REV<br>SHEET<br>REV STATU<br>OF SHEETS<br>PMIC N/A<br>ST<br>MICF<br>DF<br>THIS DRAW<br>FOR<br>DEP               | 35<br>C<br>15<br>S<br>ANDAR<br>ROCIRC<br>RAWING<br>VING IS A<br>USE BY A<br>PARTMEN           | 36<br>C<br>16<br>C<br>UIT<br>G<br>VAILAR<br>ALL<br>ITS   | 37<br>C<br>17      | 38<br>C<br>18<br>REV<br>SHE<br>PRE<br>Chr<br>CHE<br>Tim          | 39<br>C<br>19<br>;<br>ET<br>PARED<br>istophe                                  | 40<br>C<br>20<br>D BY<br>er A. Ra<br>BY<br>h                                   | 41<br>E<br>21<br>H<br>1                            | 42<br>E<br>22<br>C      | 43<br>C<br>23<br>E | 44<br>C<br>24<br>F<br>4<br>MIC<br>CO       | 45<br>E<br>25<br>F<br>5<br>DI                      | 46<br>C<br>26<br>G<br>6<br>EFEN                    | 47<br>F<br>27<br>E<br>7<br>SE SI<br>COL<br>http<br>ER, | 48<br>E<br>28<br>E<br>8<br>UPPL<br>UMBI<br>0://ww<br>, DIC<br>REM         | 29<br>E<br>9<br>Y CE<br>JS, O<br>/w.ds<br>GITAL | 30<br>H<br>10<br>NTEF<br>HIO<br>cc.dl | 31<br>E<br>11<br>COL<br>43216<br>a.mil<br>MOS,<br>RMIN | 32<br>C<br>12<br>UMB             | 33<br>C<br>13<br>US | 34<br>C |
| SHEET<br>REV<br>SHEET<br>REV STATU<br>OF SHEETS<br>PMIC N/A<br>ST<br>MICF<br>DF<br>THIS DRAW<br>FOR<br>DEP               | 35<br>C<br>15<br>S<br>ANDAR<br>ROCIRC<br>RAWING<br>VING IS A<br>USE BY<br>DARTMEN<br>ENCIES C | 36<br>C<br>16<br>C<br>UIT<br>G<br>VAILAR<br>ALL<br>ITS<br>DF THE                                   | 37<br>C<br>17      | 38<br>C<br>18<br>REV<br>SHE<br>Chr<br>CHE<br>Tim<br>APPI<br>Will | 39<br>C<br>19<br>FET<br>PAREE<br>istophe<br>CKED<br>H. Nol<br>ROVEE<br>iam K. | 40<br>C<br>20<br>D BY<br>or A. Ra<br>BY<br>h<br>D BY<br>Heckm                  | 41<br>E<br>21<br>H<br>1                            | 42<br>E<br>22<br>C<br>2 | 43<br>C<br>23<br>E | 44<br>C<br>24<br>F<br>4<br>MIC<br>CO       | 45<br>E<br>25<br>F<br>5<br>DI                      | 46<br>C<br>26<br>G<br>6<br>EFEN                    | 47<br>F<br>27<br>E<br>7<br>SE SI<br>COL<br>http<br>ER, | 48<br>E<br>28<br>E<br>8<br>UPPL<br>UMBI<br>0://ww<br>, DIC<br>REM         | 29<br>E<br>9<br>Y CE<br>JS, O<br>/w.ds<br>GITAL | 30<br>H<br>10<br>NTEF<br>HIO<br>cc.dl | 31<br>E<br>11<br>COL<br>43216<br>a.mil<br>MOS,<br>RMIN | 32<br>C<br>12<br>UMB             | 33<br>C<br>13<br>US | 34<br>C |
| SHEET<br>REV<br>SHEET<br>REV STATU:<br>OF SHEETS<br>PMIC N/A<br>PMIC N/A<br>THIS DRAW<br>FOR<br>DEP<br>AND AG<br>DEPARTM | 35<br>C<br>15<br>S<br>ANDAR<br>ROCIRC<br>RAWING<br>VING IS A<br>USE BY<br>DARTMEN<br>ENCIES C | 36<br>C<br>16<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C<br>C | 37<br>C<br>17      | 38<br>C<br>18<br>REV<br>SHE<br>Chr<br>CHE<br>Tim<br>Will<br>DRA  | 39<br>C<br>19<br>FET<br>PAREE<br>istophe<br>CKED<br>H. Nol<br>ROVEE<br>iam K. | 40<br>C<br>20<br>D BY<br>er A. Ra<br>BY<br>h<br>D BY<br>Heckm<br>APPRC<br>90-C | 41<br>E<br>21<br>H<br>1<br>auch<br>DVAL D<br>02-08 | 42<br>E<br>22<br>C<br>2 | 43<br>C<br>23<br>E | 44<br>C<br>24<br>F<br>4<br>MIC<br>CO<br>MC | 45<br>E<br>25<br>F<br>5<br>DI<br>CRO<br>DI<br>NITO | 46<br>C<br>G<br>6<br>EFEN<br>CIRC<br>COLL<br>OR, I | 47<br>F<br>27<br>E<br>7<br>SE SI<br>COL<br>http<br>ER, | 48<br>E<br>28<br>E<br>8<br>UPPL<br>UMBI<br>0://ww<br>, DIC<br>REM<br>IOLI | 29<br>E<br>9<br>Y CE<br>JS, O<br>/w.ds<br>GITAL | 30<br>H<br>10<br>NTEF<br>HIO<br>cc.dl | 31<br>E<br>11<br>COL<br>43216<br>a.mil<br>MOS,<br>RMIN | 32<br>C<br>12<br>UMB<br>S<br>BUS | 33<br>C<br>13<br>US | 34<br>C |

# 1. SCOPE

1.1 <u>Scope</u>. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.

1.2 <u>PIN</u>. The PIN is as shown in the following examples.

For device classes M and Q:



| Device type | <u>Generic number</u> | Circuit function                            |
|-------------|-----------------------|---|
| 01          | UT1553BCRTM           | Bus controller, remote terminal and monitor |

1.2.3 <u>Device class designator</u>. The device class designator is a single letter identifying the product assurance level as listed below. Since the device class designator has been added after the original issuance of this drawing, device classes M and Q designators will not be included in the PIN and will not be marked on the device.

| Device class              | Ī                 | Device requirements documentation   |               |            |  |  |  |  |
|---------------------------|-------------------|---|---------------|------------|--|--|--|--|
| Μ                         |                   | Vendor self-certification to the requirements for MIL-STD-883 compliant,<br>non-JAN class level B microcircuits in accordance with MIL-PRF-38535,<br>appendix A |               |            |  |  |  |  |
| Q or V                    | Certification and | d qualification to N  | 11L-PRF-38535 |            |  |  |  |  |
| STANDAI<br>MICROCIRCUIT I |                   | SIZE<br><b>A</b>  |               | 5962-89577 |  |  |  |  |
|                           |                   |   |               | QUEET      |  |  |  |  |

| 1.2.4 <u>Case outline(s)</u> . The case outline(s) are as designate   |  |   |            |  |  |  |  |  |  |  |
|---|--|---|------------|--|--|--|--|--|--|--|
| Outline letter Descriptive designator Terr  | <u>ninals</u>  | Package style   |            |  |  |  |  |  |  |  |
| X         CMGA15-P84         84           Y         CQCC2-J84         84           Z         CQCC1-N84         84   |  | Pin grid array<br>Leaded chip carrier w/unfor<br>Square chip carrier  | med leads  |  |  |  |  |  |  |  |
| 1.2.5 <u>Lead finish</u> . The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.   |  |   |            |  |  |  |  |  |  |  |
| 1.3 Absolute maximum ratings. 1/  |  |   |            |  |  |  |  |  |  |  |
| Supply voltage rangeDC input/dc output voltage range ( $V_{I/O}$ )DC input current ( $I_1$ )Storage temperature rangeLead tempreature (soldering 10 seconds)Maximum power dissipation, ( $P_D$ ) 2/Maximum junction temperature ( $T_J$ )Thermal resistance, junction-to-case ( $\theta_{JC}$ )Latchup immunity ( $I_{LU}$ )Duty cycle1.4 Recommended operating conditions.Supply voltage ( $V_{DD}$ )Case operating temperature range ( $T_C$ )Operating frequency ( $F_o$ )Radiation features:Total doseSingle event phenomenon (SEP) effective linear enerno upsets or latchup (see 4.4.4.4)Dose rate upset (20 ns pulse)Dose rate survivabilityNeutron irradiated1.5 Digital logic testing for device classes Q and VFault coverage measurement of manufacturing<br>logic tests (MIL-STD-883, test method 5012) | 0.3 V to<br>±10 mA<br>65°C to<br>+300°C<br>300 mW<br>+175°C<br>See MIL<br>±150 m/<br>50 ±10 p<br>21 x 10<br>gy threshold,<br>$3/$<br>$3/$<br>$3/$<br>$3/$<br>$3/$<br>> 1 x 10 <sup>1</sup> | (V <sub>DD</sub> +0.3 V)<br>+150°C<br>-STD-1835<br>A<br>bercent<br>5.5 V<br>+125°C<br>± .01 percent<br><sup>6</sup> Rads (Si)<br>V- cm <sup>2</sup> /mg |            |  |  |  |  |  |  |  |
| 1/       Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.         2/       Must withstand the added P <sub>D</sub> due to short circuit test (e.g., los).         3/       When characterized as a result of the procuring activities request, the condition will be specified.         STANDARD SIZE A         MICROCIRCUIT DRAWING   |  |   |            |  |  |  |  |  |  |  |
| DEFENSE SUPPLY CENTER COLUMBUS<br>COLUMBUS, OHIO 43216-5000   |  | REVISION LEVEL<br>E   | SHEET<br>3 |  |  |  |  |  |  |  |

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#### 2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those listed in the issue of the Department of Defense Index of Specifications and Standards (DoDISS) and supplement thereto, cited in the solicitation.

#### SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

#### STANDARDS

DEPARTMENT OF DEFENSE

| MIL-STD-883 -  | Test Method Standard Microcircuits.                    |
|----------------|--|
| MIL-STD-1835 - | Interface Standard Electronic Component Case Outlines. |

#### HANDBOOKS

DEPARTMENT OF DEFENSE

| MIL-HDBK-103 - | List of Standard Microcircuit Drawings. |
|----------------|---|
| MIL-HDBK-780 - | Standard Microcircuit Drawings.         |

(Unless otherwise indicated, copies of the specification, standards, and handbooks are available from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

## 3. REQUIREMENTS

3.1 <u>Item requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.

3.1.1 Microcircuit die. For the requirements for microcircuit die, see appendix A to this document.

3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.

3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Functional block diagram. The functional block diagram shall be as specified on figure 2.

3.2.4 Switching test circuit and waveforms. The switching test circuit and waveforms shall be as specified on figure 3.

3.2.5 Radiation exposure circuit. The radiation exposure circuit shall be as specified on figure 4.

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br><b>A</b> |                | 5962-89577 |
|----------------------------------|------------------|----------------|------------|
| DEFENSE SUPPLY CENTER COLUMBUS   |                  | REVISION LEVEL | SHEET      |
| COLUMBUS, OHIO 43216-5000        |                  | F              | <b>4</b>   |

3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table IA and shall apply over the full case operating temperature range.

3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table IA.

3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-HDBK-103. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.

3.5.1 <u>Certification/compliance mark</u>. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

3.6 <u>Certificate of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.

3.8 <u>Notification of change for device class M</u>. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-PRF-38535, appendix A.

3.9 <u>Verification and review for device class M</u>. For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 105 (see MIL-PRF-38535, appendix A).

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br><b>A</b> |                | 5962-89577 |
|----------------------------------|------------------|----------------|------------|
| DEFENSE SUPPLY CENTER COLUMBUS   |                  | REVISION LEVEL | SHEET      |
| COLUMBUS, OHIO 43216-5000        |                  | F              | 5          |

|   | TA               | BLE IA. Electrical per   | rformance       | characteri       | istics.           |                         |                         |         |
|---|------------------|--|-----------------|------------------|-------------------|-------------------------|-------------------------|---------|
| Test  | Symbol           | $\begin{array}{c} Conditions \\ 4.5 \ V \leq V_{DD} \leq 5.5 \\ -55^{\circ}C \leq T_C \leq +12 \\ unless \ otherwise \ sp \end{array}$ | 25°C            | Group<br>subgrou |                   | Li                      | mits                    | Unit    |
|   |                  |  |                 |                  |                   | Min                     | Max                     |         |
| Low level input voltage<br>TTL inputs                       | VIL              |  |                 | 1, 2, 3          | All               |                         | 0.8                     | V       |
| High level input voltage<br>TTL inputs <u>2</u> /           | VIH              |  |                 | 1, 2, 3          | All               | 2.0                     |                         | V       |
| Input leakage current<br>TTL inputs                         | l <sub>IN</sub>  | $V_{IN} = V_{DD} \text{ or } V_{SS}$   |                 | 1, 2, 3          | All               | -1                      | 1                       | μΑ      |
|   |                  | M, D, P,L, R   | , F, G, H       | 1                | All               | -10                     | 10                      | -       |
| With pull-up resistors                                      |                  | V <sub>IN =</sub> V <sub>DD</sub>  |                 | 1, 2, 3          | All               | -1                      | 1                       |         |
|   |                  | M, D, P,L, F   | R, F, G, H      | 1                | All               | -10                     | 10                      |         |
| With pull-up resistors                                      |                  | $V_{IN} = V_{SS}$  |                 | 1, 2, 3          | All               | -550                    | -80                     |         |
|   |                  | M, D, P,L, R   | , F, G, H       | 1                | All               | -900                    | -150                    |         |
| Low level output voltage<br>TTL outputs                     | V <sub>OL</sub>  | I <sub>OL</sub> = 3.2 mA   |                 | 1, 2, 3          | All               |                         | 0.4                     | V       |
| Low level output voltage<br>CMOS outputs                    | V <sub>OL2</sub> | I <sub>OL</sub> = 50 μA  |                 | 1, 2, 3          | 3 All             |                         | V <sub>SS</sub><br>+0.1 | V       |
| High level output voltage<br>TTL outputs                    | V <sub>OH</sub>  | I <sub>OH</sub> = -400 μA  |                 | 1, 2, 3          | All               | 2.4                     |                         | V       |
| High level output voltage<br>CMOS outputs                   | V <sub>OH2</sub> | I <sub>OH</sub> = -50 μA   |                 | 1, 2, 3          | 3 All             | V <sub>DD</sub><br>-0.1 |                         | V       |
| Three-state output leakage<br>Current TTL outputs           | l <sub>oz</sub>  | $V_{OUT} = V_{DD} \text{ or } V_{SS}$  |                 | 1, 2, 3          | All               | -10                     | 10                      | μA      |
| Short-circuit output current <u>3/ 4</u> /                  | los              | $V_{DD} = 5.5 \text{ V}, \text{ V}_{OUT} =$  | V <sub>DD</sub> | 1, 2, 3          | All               |                         | 110                     | mA      |
|   |                  | $V_{DD} = 5.5 \text{ V}, \text{ V}_{OUT} =$  | 0 V             | 1, 2, 3          | All               | -110                    |                         | mA      |
| Quiescent current <u>5</u> / <u>14</u> /                    | Q <sub>IDD</sub> |  |                 | 1, 3             | All               |                         | 35                      | μA      |
|   |                  |  |                 | 2                |                   |                         | 1                       | mA      |
| Average operating current <u>3/6/</u>                       | I <sub>DD</sub>  | f = 12 MHz, C <sub>L</sub> = 50  | pF              | 1, 2, 3          | All               |                         | 50                      | mA      |
| Input capacitance   | CIN              | See 4.4.1c   | _               | 4                | All               |                         | 10                      | pF      |
| Output capacitance  | COUT             |  |                 | 4                | All               |                         | 15                      | pF      |
| Bidirect I/O capacitance<br>See footnotes at end of table.  | C <sub>IO</sub>  |  |                 | 4                | All               |                         | 20                      | pF      |
|   | IDARD            |  | SIZE            | E                |                   |                         |                         |         |
| MICROCIRC   |                  | VING   | Α               |                  |                   |                         |                         | 2-89577 |
| DEFENSE SUPPLY CENTER COLUMBUS<br>COLUMBUS, OHIO 43216-5000 |                  |  |                 | F                | REVISION LEV<br>G | EL                      | SHEET                   | 6       |

|   | TABLE              | IA. Electrical performa   | nce cha      | racteristics       | s Continued      |              |              |      |
|---|--------------------|---|--------------|--------------------|------------------|--------------|--------------|------|
| Test  | Symbol             | $\begin{array}{l} Conditions \\ 4.5 \ V \leq V_{DD} \leq 5. \\ -55^{\circ}C \leq T_C \leq +125^{\circ}C \\ unless \ otherwise \ spectrum{}$ | C <u>1</u> / | Group /<br>subgrou |                  | Li           | mits         | Unit |
|   |                    |   |              |                    |                  | Min          | Max          |      |
| Functional tests  |                    | See 4.4.1d  |              | 7, 8               |                  |              |              |      |
| DMACK (L) to DMAR<br>high impedance                         | T <sub>SHL1</sub>  | See figure 3<br>BURST DMA timing  | 0.11         | 9, 10, 11          | All              | 0            | 10           | ns   |
|   | T <sub>PZL2</sub>  | M,D,P,L,R,F,<br>See figure 3  | ,G,H         | 9, 10, 11          | All              | -5<br>0      | 5<br>45      | ns   |
| DMAG (L) to DMACK (L)<br>                                   |                    | BURST DMA timing  | -            |                    |                  |              |              |      |
| DMAG (L) to TSCTL (L)<br><u>15</u> /                        | T <sub>PHL2</sub>  |   |              | 9, 10, 11          | All              | 2x<br>MCLK   | 4x<br>MCLK   | ns   |
| TSCTL (L) to ADDRESS  | T <sub>PzL1</sub>  |   |              | 9, 10, 11          | All              | 0            | 40           | ns   |
| valid <u>3</u> /  |                    | M,D,P,L,R,  | F.G.H        |                    |                  | -2           | 40           |      |
| RWR / RRD (H)<br>to DMACK (H)                               | t <sub>HLH2</sub>  | See figure 3<br>BURST DMA timing  | , - ,        | 9, 10, 11          | All              | THMC1<br>-10 | THMC1<br>+10 | ns   |
| TSCTL (L) to RWR / RRD<br>(L)                               | t <sub>PHL3</sub>  | -   | -            | 9, 10, 11          | All              | MCLK<br>-20  | MCLK<br>+20  | ns   |
| DMAG (L) to DMAG (H)<br><u>15</u> /                         | t <sub>PW2</sub>   |   | -            | 9, 10, 11          | All              | MCLK         | 6xMCLK       | ns   |
| DMAR (L) to BURST(H)  | t <sub>OOZL1</sub> |   |              | 9, 10, 11          | All              | -10          | 10           | ns   |
| DMAR (L) to DMAG (L)<br><u>8/ 15</u> /                      | t <sub>PHL4</sub>  | MCLK = 12 MHz   |              | 9, 10, 11          | All              | 0            | 1.9 (0.8)    | μs   |
|   |                    | MCLK = 6 MHz<br>See figure 3<br>BURST DMA timing  |              |                    |                  | 0            | 3.5 (1.9)    |      |
| ADDRESS valid to<br>RRD (L)                                 | t <sub>SHL1</sub>  | See figure 3<br>DMA read timing   |              | 9, 10, 11          | All              | THMC2<br>-10 | THMC2<br>+5  | ns   |
| (Address setup)   |                    | M,D,P,L,R,F   | F,G,H        |                    |                  | THMC2<br>-10 | THMC2<br>+10 |      |
| RRD (L) to RRD (H)  | T <sub>PW1</sub>   | See figure 3<br>DMA read timing   |              | 9, 10, 11          | All              | MCLK<br>-10  | MCLK<br>+5   | ns   |
| RRD (H) to ADDRESS<br>high impedance<br>(ADDRESS hold)      | t <sub>HLZ2</sub>  |   | -            | 9, 10, 11          | All              | THMC1<br>-10 | THMC1<br>+10 | ns   |
| See footnotes at end of table                               |                    |   |              |                    |                  |              |              |      |
| STAI<br>MICROCIRC   | NDARD<br>SUIT DRA  | WING  |              | ize<br><b>A</b>    |                  |              | 5962-8       | 9577 |
| DEFENSE SUPPLY CENTER COLUMBUS<br>COLUMBUS, OHIO 43216-5000 |                    |   |              |                    | REVISION LE<br>E | VEL          | SHEET<br>7   |      |

| Test   | TABLE IA           | A. <u>Electrical performa</u><br>Conditions<br>$4.5 V \le V_{DD} \le 5$                        | Grou          | ıp A  | ntinued<br>Device<br>type | Lir                   | nits                 | Unit  |
|--|--------------------|--|---------------|-------|---------------------------|-----------------------|----------------------|-------|
|  |                    | $4.5 \text{ V} \leq \text{V}_{DD} \leq 3$<br>-55°C $\leq T_C \leq +125$<br>unless otherwise sp | °C <u>1</u> / | Jups  | type                      |                       |                      |       |
|  |                    |  |               |       |                           | Min                   | Max                  |       |
| RRD (H) to DATA high impedance (DATA hold)             | t <sub>HLZ1</sub>  | See figure 3<br>DMA read timing  | 9, 10,        | 11    | All                       | 5                     |                      | ns    |
| DATA valid to RRD (H)<br>(DATA setup)                  | t <sub>SLH1</sub>  |  | 9, 10,        | 11    | All                       | 40                    |                      | ns    |
| MCLK(H) to MCLKD2(H)                                   | t <sub>PLH1</sub>  |  | 9, 10,        | 11    | All                       | 0                     | 40                   | ns    |
| MCLK(H) to<br>TSCTL/MEMCSO (L)                         | t <sub>PLH2</sub>  |  | 9, 10,        | 11    | All                       | 0                     | 40                   | ns    |
| MCLK(H) to RRD (L)                                     | T <sub>IOHL1</sub> |  | 9, 10,        | 11    | All                       | 0                     | 60                   | ns    |
| ADDRESS valid to RWR (L)<br>(ADDRESS setup)            | t <sub>SHL1</sub>  | See figure 3<br>DMA write timing<br>M,D,P,L,R,F,G  | 9, 10,<br>6,H | 11    | All                       | THMC2<br>-10<br>THMC2 | THMC2<br>+5<br>THMC2 | ns    |
| RWR (L) to DATA valid <u>13</u> /                      | t <sub>OOZL1</sub> | See figure 3<br>DMA write timing   | 9, 10,        | 11    | All                       | -10<br>0              | +10<br>30            | ns    |
|  |                    | M,D,P,L,R,F,C  |               |       |                           | -5                    | 30                   |       |
| RWR (H) to DATA high<br>impedance DATA hold)           | t <sub>HLZ1</sub>  | See figure 3<br>DMA write timing   | 9, 10,        | 11    | All                       | THMC1<br>-10          | THMC1<br>+10         | ns    |
| RWR (H) to ADDRESS high<br>impedance<br>(ADDRESS hold) | t <sub>HLZ2</sub>  |  | 9, 10,        | 11    | All                       | THMC1<br>-10          | THMC1<br>+10         | ns    |
| RWR (L) to RWR (H)                                     | t <sub>PW1</sub>   |  | 9, 10,        | 11    | All                       | MCLK<br>-10           | MCLK<br>+5           | ns    |
| MCLK(H) to MCLKD2(H)                                   | t <sub>PLH1</sub>  |  | 9, 10,        | 11    | All                       | 0                     | 40                   | ns    |
| MCLK(H) to<br>TSCTL/MEMCSO (L)                         | t <sub>PLH2</sub>  |  | 9, 10,        | 11    | All                       | 0                     | 40                   | ns    |
| MCLK(H) to RWR (L)                                     | t <sub>IOHL1</sub> |  | 9, 10,        | 11    | All                       | 0                     | 60                   | ns    |
| See footnotes at end of table.                         |                    |  |               |       |                           |                       |                      |       |
|  |                    |  |               |       |                           |                       |                      |       |
|  |                    |  |               |       |                           |                       |                      |       |
|  |                    |  |               |       |                           |                       |                      |       |
| STAN<br>MICROCIRCU                                     | DARD<br>JIT DRAV   | VING   | SIZE<br>A     |       |                           |                       | 5962-                | 89577 |
| DEFENSE SUPPLY (<br>COLUMBUS, O                        |                    |  |               | REVIS | SION LE'<br>E             | VEL                   | SHEET 8              | 3     |

|  | TABLE              | IA. Electrical performa   | nce chai     | racteristics        | Continued        |        |      |          |
|--|--------------------|---|--------------|---------------------|------------------|--------|------|----------|
| Test   | Symbol             | $\begin{array}{l} \mbox{Conditions} \\ \mbox{4.5 V} \leq V_{DD} \leq 5.5 \\ \mbox{-}55^\circ C \leq T_C \leq +125^\circ C \\ \mbox{unless otherwise spe} \end{array}$ | C <u>1</u> / | Group /<br>subgroup |                  | Limits |      | Unit     |
|  |                    |   |              |                     |                  | Min    | Max  |          |
| ADDRESS valid to DATA<br>Valid <u>9</u> /  | TOOZH2             | See figure 3<br>Register read timing  |              | 9, 10, 11           | All              |        | 80   | ns       |
| RD + CS (H) to DATA high<br>impedance (DATA<br>hold)   | t <sub>HLH2</sub>  |   |              | 9, 10, 11           | All              | 5      | 50   | ns       |
| RD + CS (L) to DATA valid<br>(DATA access) <u>9</u> /  | t <sub>ооzн1</sub> |   |              | 9, 10, 11           | All              |        | 60   | ns       |
| RD + CS (H) to ADDRESS<br>high impedance<br>(ADDRESS hold)   | t <sub>HLH1</sub>  |   |              | 9, 10, 11           | All              | 5      |      | ns       |
| $\overline{RD} + \overline{CS}$ (L) to<br>$\overline{RD} + \overline{CS}$ (H)                        | t <sub>PW1</sub>   |   |              | 9, 10, 11           | All              | 60     |      | ns       |
| $\overline{RD} + \overline{CS} (H) \text{ to}$ $\overline{RD} + \overline{CS} (L)$ $\underline{15}/$ | t <sub>PW2</sub>   |   |              | 9, 10, 11           | All              | 80     |      | ns       |
| ADDRESS valid to<br>WR + CS (L)<br>(ADDRESS setup)   | t <sub>SHL1</sub>  | See figure 3<br>Register write timing   |              | 9, 10, 11           | All              | 60     |      | ns       |
| DATA valid to<br>WR + CS (L)<br>(DATA setup)   | t <sub>SHL2</sub>  |   |              | 9, 10, 11           | All              | 5      |      | ns       |
| $\frac{\overline{WR} + \overline{CS} (L) \text{ to}}{WR + \overline{CS} (H)}$                        | t <sub>PW1</sub>   |   |              | 9, 10, 11           | All              | 60     |      | ns       |
| WR + CS (H) to DATA<br>high<br>impedance (DATA<br>hold)  | t <sub>HLH1</sub>  |   |              | 9, 10, 11           | All              | 10     |      | ns       |
| WR + CS (H) to<br>ADDRESS<br>high impedance<br>(ADDRESS hold)  | t <sub>HLH2</sub>  |   |              | 9, 10, 11           | All              | 10     |      | ns       |
| $\overline{WR} + \overline{CS} (H) \text{ to} \\ \overline{WR} + \overline{CS} (L)  \underline{15}/$ | t <sub>PW2</sub>   |   |              | 9, 10, 11           | All              | 80     |      | ns       |
| See footnotes at end of table  | ).                 |   |              |                     |                  |        |      |          |
| STA<br>MICROCIRC   | NDARD<br>SUIT DRA  | WING  |              | ZE<br><b>A</b>      |                  |        | 59   | 62-89577 |
| DEFENSE SUPPLY CENTER COLUMBUS<br>COLUMBUS, OHIO 43216-5000  |                    |   |              |                     | REVISION LE<br>E | EVEL   | SHEE | т<br>9   |

|   | TABLE              | IA. Electrical performa  | nce cha | aracteristic        | <u>s</u> Continued | l             |                    |          |
|---|--------------------|--|---------|---------------------|--------------------|---------------|--------------------|----------|
| Test                                      | Symbol             | $\begin{array}{c} \text{Conditions} \\ 4.5 \text{ V} \leq \text{V}_{\text{DD}} \leq 5.5 \\ \text{-}55^{\circ}\text{C} \leq \text{T}_{\text{C}} \leq \text{+}125^{\circ}\text{C} \\ \text{unless otherwise spectrum} \end{array}$ | 1/      | Group /<br>subgroup |                    | Lir           | nits               | Unit     |
|   |                    |  |         |                     |                    | Min           | Max                |          |
| RD (L) to RRD (L)                         | t <sub>PHL1</sub>  | See figure 3<br>Dual port interface tim  | ning    | 9, 10, 11           | All                | 0             | 30                 | ns       |
| WR (L) to RWR (L)                         | t <sub>PHL2</sub>  |  |         | 9, 10, 11           | All                | 0             | 30                 | ns       |
| MEMCSI (L) to<br>MEMCSO (L)               | t <sub>PHL3</sub>  |  |         | 9, 10, 11           | All                | 0             | 30                 | ns       |
| MEMWIN (H) to DMA<br>activity <u>10</u> / | t <sub>OOLH1</sub> | See figure 3<br>Memory window (RT)   | mode    | 9, 10, 11           | All                | 9             |                    | μs       |
| MEMWIN (L) to<br>MEMWIN (H) <u>10</u> /   | t <sub>PW1</sub>   | -  |         | 9, 10, 11           | All                | 0             | <u>10</u> /        | μs       |
| Data word to DMA<br>Activity <u>15</u> /  | t <sub>PZL1</sub>  |  |         | 9, 10, 11           | All                | 0             | 4                  | μs       |
| DMAG (L) to DMAGO (L)<br><u>12</u> /      | t <sub>PHL1</sub>  | See figure 3<br>Arbitration when DMA<br>asserted before arbitra  |         | 9, 10, 11           | All                | 0             | 30                 | ns       |
| DMACK (L) to DMAR<br>high impedance       | t <sub>SHL1</sub>  | M,D,P,L,R,F,G,I  | H       | 9, 10, 11           | All                | 0<br>-5       | 10<br>5            | ns       |
| MCLK(H) to MCLKD2(H)                      | t <sub>PLH2</sub>  |  |         | 9, 10, 11           | All                | 0             | 40                 | ns       |
| MEMWIN (H) to<br>DMAR (L) <u>10</u> /     | t <sub>OOLH2</sub> | See figure 3<br>Interrupt log list entry<br>operation timing   |         | 9, 10, 11           | All                | 9             |                    | μs       |
| TSCTL (H) to<br>STDINTP / STDINTL (L)     | t <sub>OOLH1</sub> |  |         | 9, 10, 11           | All                |               | 1                  | μs       |
| STDINTP (L) to<br>STDINTP (H)             | t <sub>PW1</sub>   |  |         | 9, 10, 11           | All                | 320           | 340                | ns       |
| DMACK (L) to RWR (L)                      | t <sub>OOHL1</sub> | -  |         | 9, 10, 11           | All                | 3xMCLK<br>-10 | 5xMCLK             | ns       |
| DMAG (L) to<br>STDINTL (L)                | t <sub>OOHL2</sub> |  |         | 9, 10, 11           | All                | 8xMCLK        | 10x<br>MCLK<br>+40 | ns       |
| See footnotes on next page                | ).                 | 1  |         | 1                   | I                  | 1             | 1                  | <u> </u> |
| STA<br>MICROCIR(                          | NDARD              | AWING  |         | SIZE<br><b>A</b>    |                    |               | 5962-8             | 9577     |
| DEFENSE SUPPLY<br>COLUMBUS,               |                    |  |         |                     | REVISION L<br>H    |               | SHEET<br>10        | )        |

| TABLE IA | Electrical | performance | characteristics. | - Continued |
|----------|------------|-------------|------------------|-------------|
|          | Licothoai  | periornance | characteristics. | Continucu   |

<u>1</u>/ Devices supplied to this drawing are characterized at all levels M, D, P, L, R, F, G, and H of irradiation. However, this device is only tested at the 'H' level. Pre and Post irradiation values are identical unless otherwise specified in Table IA. When performing post irradiation electrical measurements for any RHA level,  $T_A = +25^{\circ}C$ .

2/ Radiation hardened technology shall have a V<sub>IH</sub> pre-irradiation limit of 2.2 V.

3/ Guaranteed to the limit specified in table IA. Tested only at initial qualification, and after any design or process changes which may affect this characteristic.

4/ Not more than one output may be shorted at a time for a maximum duration of one second.

5/ All inputs with internal pull-ups should be left floating. All other inputs should be tied high or low.

- 6/ Includes current through input pull-up. Instantaneous surge currents on the order of 1 ampere can occur during output switching. Voltage supply should be adequately sized and decoupled to handle a large current surge.
- <u>7</u>/ DMAG must be asserted at least 45 ns prior to the rising edge of MCLKD2 in order to be recognized for the next MCLKD2 cycle. If DMAG is not asserted at least 45 ns prior to the rising edge of MCLKD2, DMAG is not recognized until the following MCLKD2 cycle.
- 8/ Number in parentheses indicates the longest DMAR (L) to DMAG(L) allowed during worst-case bus switching conditions in order to meet MIL-STD-1553B RT response time. The number not in parentheses applies to all other circumstances.
- <u>9</u>/ User must adhere to both  $T_{OOZH1}$  and  $T_{OOZH2}$  timing constraints to ensure valid data.
- 10/ MEMWIN is an internal test pin only and should be considered a floating pin and not for use.
- <u>11</u>/ The pulse width = (11  $\mu$ s t<sub>DMA</sub> t<sub>PZL1</sub>) where t<sub>DMA</sub> is the time to complete DMA activity.
- 12/ When DMAG is asserted before DMAR, the DMAG signal passes through device 01 as DMAGO.
- 13/ Timing is not valid for RT timer field of message status word. The timer value may update during a DMA memory write.
- 14/ Guaranteed to pre-and post-irradiation limits.
- 15/ Guaranteed by functional test.

TABLE IB. SEP test limits . 1/ 2/ 3/

| Device<br>type | T <sub>A</sub> =<br>Temperature<br>±10°C <u>4</u> / | Memory<br>pattern | $V_{CC} = 4.5 V$ $T_{A} = +25^{\circ}C$ |   |                         |  | Bias for latch-<br>up test V <sub>CC</sub><br>=5.5 V no<br>latch-up<br>LET 4/ |
|----------------|---|-------------------|---|---|-------------------------|--|---|
|                |   |                   | Effective<br>LET no<br>upsets           | Maximum<br>device<br>cross section<br>cm <sup>2</sup> /bit<br>(LET = 128) | T <sub>A</sub> = +125°C |  |   |
| All            | +25°C   | <u>5</u> /        | ≥ 27                                    | $\leq 8.5 \times 10^{-7}$   | ≤ 80                    |  |   |

NOTE: Devices that contain cross coupled resistance must be tested at the maximum rated T<sub>A</sub>

1/ For SEP test conditions, see 4.4.4.4 herein.

- 2/ Technology characterization and model verification supplemented by in-line data may be used in lieu of end-of-line testing. Test plan must be approved by TRB and qualifying activity.
- 3/ Values will be added when they become available. Rad hard devices have not yet been tested for SEP.
- $\frac{1}{4}$  Worst case temperature T<sub>A</sub> = +125°C.

5/ For memories only.

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br><b>A</b> |                | 5962-89577 |
|----------------------------------|------------------|----------------|------------|
| DEFENSE SUPPLY CENTER COLUMBUS   |                  | REVISION LEVEL | SHEET      |
| COLUMBUS, OHIO 43216-5000        |                  | E              | 11         |

| Device                   |        |                     | 01                                  |         |
|--------------------------|--------|---------------------|-------------------------------------|---------|
| type<br>Case<br>outlines | Х      | Y, Z                | Description                         |         |
| Terminal<br>symbol       | Nu     | minal<br>mbers      |                                     |         |
| V <sub>SS</sub>          | F3     | 1                   | Ground                              |         |
| D7                       | F1     | 2                   | Bit 7 of the data bus, TTB          |         |
| D6                       | G1     | 3                   | Bit 6 of the data bus, TTB          |         |
| D5                       | G2     | 4                   | Bit 5 of the data bus, TTB          |         |
| D4                       | G3     | 5                   | Bit 4 of the data bus, TTB          |         |
| D3                       | H1     | 6                   | Bit 3 of the data bus, TTB          |         |
| D2                       | H2     | 7                   | Bit 2 of the data bus, TTB          |         |
| D1                       | J1     | 8                   | Bit 1 of the data bus, TTB          |         |
| D0                       | K1     | 9                   | Bit 0, LSB of the data bus, TTB     |         |
| MRST                     | J2     | 10                  | Master Reset, Active low, TTL input |         |
| BCRTSEL                  | L1     | 11                  | BC/RT Select, TUI                   |         |
| LOCK                     | K2     | 12                  | Lock, Active high, TUI              |         |
| TAZ                      | K3     | 13                  | Transmit (Channel) A Z, TO          |         |
| ТАО                      | L2     | 14                  | Transmit (Channel) A O, TO          |         |
| RAZ                      | L3     | 15                  | Receive (Channel) A Z, TI           |         |
| RAO                      | K4     | 16                  | Receive (Channel) A O, TI           |         |
| TBZ                      | L4     | 17                  | Transmit (Channel) B Z, TO          |         |
| ТВО                      | K6     | 18                  | Transmit (Channel) B O, TO          |         |
| RBZ                      | K5     | 19                  | Receive (Channel) B Z, TI           |         |
| RBO                      | L5     | 20                  | Receive (Channel) B O, TI           |         |
| CLK                      | J5     | 21                  | Clock, TI                           |         |
| V <sub>SS</sub>          | J6     | 22                  | Ground                              |         |
| V <sub>DD</sub>          | L6     | 23                  | +5.0 V                              |         |
|                          |        | FIGURE <sup>-</sup> | I. <u>Terminal connections.</u>     |         |
| ST/<br>MICROCIR          | ANDARD |                     | SIZE<br>A                           | 5962-89 |

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# DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000

| Type<br>Case       | Х             | Y, Z | Description                             |  |
|--------------------|---------------|------|---|--|
| Outlines           |               |      |   |  |
| Terminal<br>Symbol | Termi<br>Numb |      |   |  |
| EXTOVR             | L7            | 24   | External Override, Active low, TUI      |  |
| TIMERON            | K7            | 25   | (RT) Timer On, Active low, TO           |  |
| CHA/B              | J7            | 26   | Channel A/B, TO                         |  |
| COMSTR             | L8            | 27   | (RT) Command Strobe, Active low, TO     |  |
| RTAO               | K8            | 28   | Remote Terminal Address Bit 0, LSB, TUI |  |
| RTA1               | L9            | 29   | Remote Terminal Address Bit 1, TUI      |  |
| RTA2               | L10           | 30   | Remote Terminal Address Bit 2, TUI      |  |
| RTA3               | K9            | 31   | Remote Terminal Address Bit 3, TUI      |  |
| RTA4               | L11           | 32   | Remote Terminal Address Bit 4, TUI      |  |
| RTPTY              | K10           | 33   | Remote Terminal Address, Parity, TUI    |  |
| A0                 | J10           | 34   | Bit 0 (LSB) of the address bus, TTB     |  |
| A1                 | K11           | 35   | Bit 1 of the address bus, TTB           |  |
| A2                 | J11           | 36   | Bit 2 of the address bus, TTB           |  |
| A3                 | H10           | 37   | Bit 3 of the address bus, TTB           |  |
| A4                 | H11           | 38   | Bit 4 of the address bus, TTB           |  |
| A5                 | G9            | 39   | Bit 5 of the address bus, TTB           |  |
| A6                 | G10           | 40   | Bit 6 of the address bus, TTB           |  |
| A7                 | G11           | 41   | Bit 7 of the address bus, TTB           |  |
| V <sub>SS</sub>    | F10           | 42   | Ground                                  |  |
| V <sub>DD</sub>    | F9            | 43   | +5.0 V                                  |  |
| A8                 | E9            | 44   | Bit 8 of the address bus, TTO           |  |
|                    |               |      | Bit 8 of the address bus, TTO           |  |

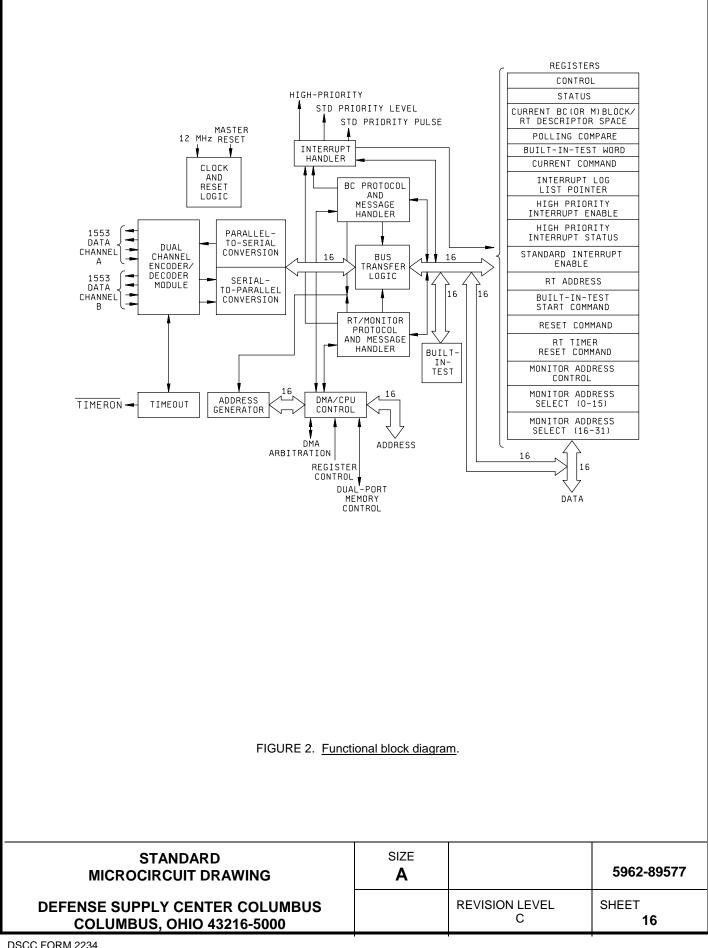
| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br><b>A</b> |                | 5962-89577 |
|----------------------------------|------------------|----------------|------------|
| DEFENSE SUPPLY CENTER COLUMBUS   |                  | REVISION LEVEL | SHEET      |
| COLUMBUS, OHIO 43216-5000        |                  | C              | 13         |

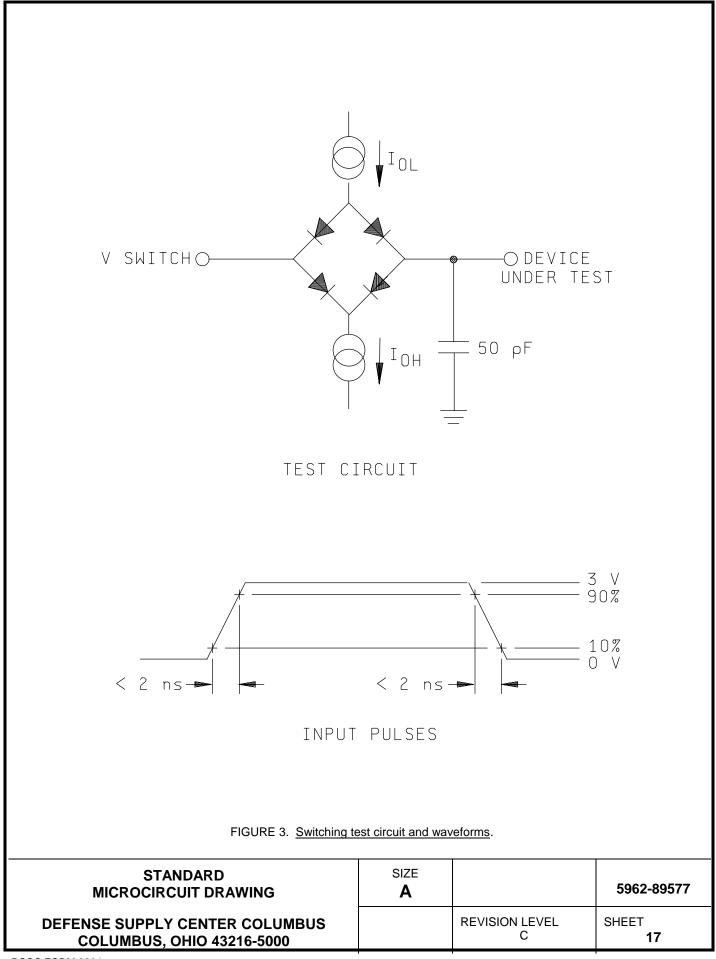
| Device<br>Type                     |                    |      | 01   |  |
|------------------------------------|--------------------|------|--|--|
| Case<br>outlines                   | Х                  | Y, Z | Description  |  |
| Terminal<br>Symbol                 | Terminal<br>Number |      |  |  |
| A9                                 | E11                | 45   | Bit 9 of the address bus, TTO                                      |  |
| A10                                | E10                | 46   | Bit 10 of the address bus, TTO                                     |  |
| A11                                | F11                | 47   | Bit 11 of the address bus, TTO                                     |  |
| A12                                | D11                | 48   | Bit 12 of the address bus, TTO                                     |  |
| A13                                | D10                | 49   | Bit 13 of the address bus, TTO                                     |  |
| A14                                | C11                | 50   | Bit 14 of the address bus, TTO                                     |  |
| A15                                | B11                | 51   | Bit 15 of the address bus, TTO                                     |  |
| RWR                                | C10                | 52   | RAM Write, Active low, TO  |  |
| RRD                                | A11                | 53   | RAM Read (Active low)  |  |
| MEMCSO                             | B10                | 54   | Memory Chip Select Out, Active low, TO                             |  |
| TSCTL                              | B9                 | 55   | Three-State Control, Active low, TO                                |  |
| DMAR                               | A10                | 56   | DMA Request, Active low, inactive state is high impedance,         |  |
| DMAG                               | A9                 | 57   | TTO<br>DMA Grant, Active low, TI                                   |  |
| DMACK                              | B8                 | 58   | DMA Acknowledge, Active low, inactive state is high impedance, TTO |  |
| MEMCSI                             | A8                 | 59   | Memory Chip Select In, Active low, TI                              |  |
| WR                                 | C7                 | 60   | Write, Active low, TI  |  |
| RD                                 | B7                 | 61   | Read, Active low, TI   |  |
|                                    | A7                 | 62   | Chip Select, Active low, TI  |  |
| V <sub>SS</sub>                    | B6                 | 63   | Ground   |  |
| v <sub>SS</sub><br>V <sub>DD</sub> | C6                 | 64   | +5.0 V   |  |
| MCLK                               | C5                 | 65   | Memory Clock, TI   |  |
| AEN                                | A5                 | 66   | Address Enable, Active high, TI                                    |  |

FIGURE 1. Terminal connections. - Continued

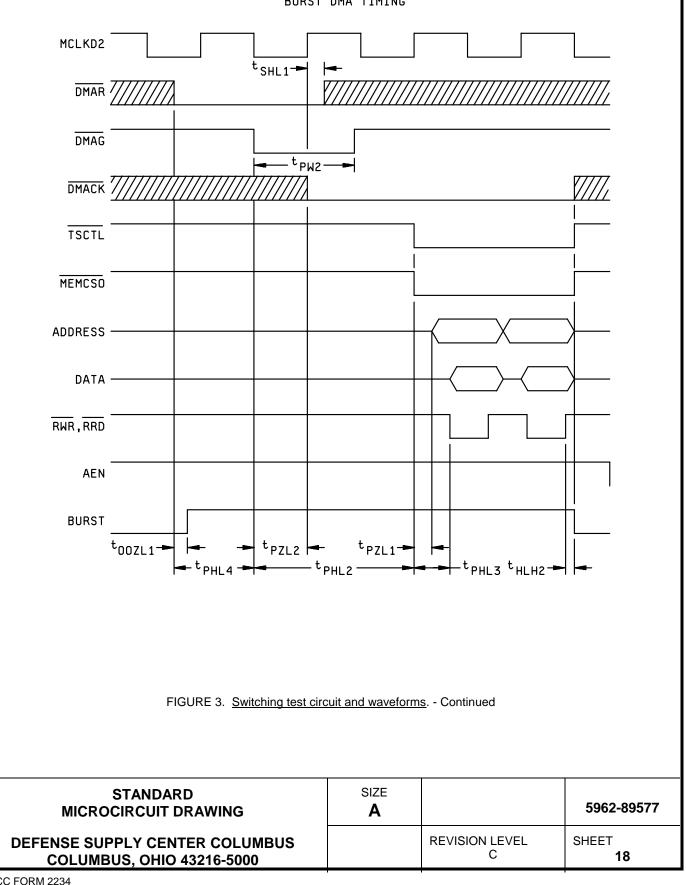
| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br>A |                | 5962-89577 |
|----------------------------------|-----------|----------------|------------|
| DEFENSE SUPPLY CENTER COLUMBUS   |           | REVISION LEVEL | SHEET      |
| COLUMBUS, OHIO 43216-5000        |           | C              | 14         |

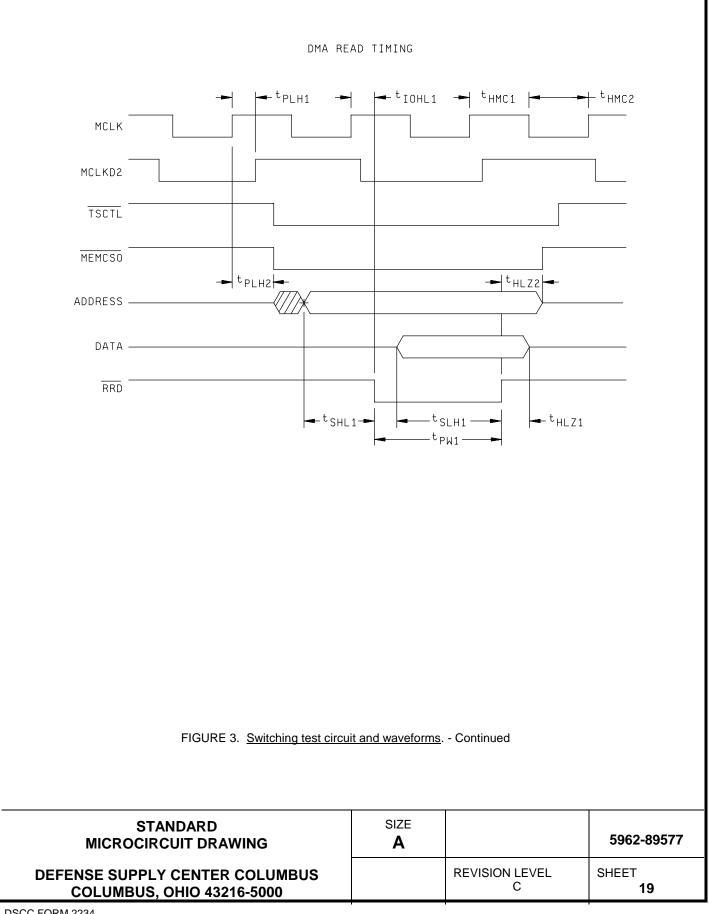
| Device<br>Type     |   |   |  | 01                   |  |           |
|--------------------|---|---|--|----------------------|--|-----------|
| Case<br>Outlines   | Х   | Y, Z  |  |                      |  |           |
| Terminal<br>symbol |   | ninal<br>bers   |  | C                    | Description  |           |
| DMAGO              | B5  | 67  | DMA grant of   | out, Iow, TO         |  |           |
| STDINTL            | A6  | 68  |  |                      | e low, inactive state is higl                        | h         |
| STDINTP            | A4  | 69  | impedance,<br>Standard in  | terrupt pulse, activ | ve low, TO   |           |
| HPINT              | B4  | 70  |  | interrupt active lo  | ow, inactive state is high ir                        | npedance, |
| MCLKD2             | A3  | 71  | TTO<br>Memory clo  | ck divided by two,   | то   |           |
| SSYSF              | A2  | 72  | Subsystem  | fail, active high, T | I  |           |
| MEMWIN             | B3  | 73  | Memory acc   | cess window, activ   | re low, TO   |           |
| BURST              | A1  | 74  | BURST, DM  | IA cycle, multiple   | word DMA access, active                              | high, TO  |
| BCRTF              | B2  | 75  | BCRT fail, a   | ctive high, TO       |  |           |
| D15                | C2  | 76  | Bit 15 MSB   | of the data bus, T   | ТВ   |           |
| D14                | B1  | 77  | Bit 14 of the  | data bus, TTB        |  |           |
| D13                | C1  | 78  | Bit 13 of the  | data bus, TTB        |  |           |
| D12                | D2  | 79  | Bit 12 of the  | data bus, TTB        |  |           |
| D11                | D1  | 80  | Bit 11 of the  | data bus, TTB        |  |           |
| D10                | F2  | 81  | Bit 10 of the  | data bus, TTB        |  |           |
| D9                 | E2  | 82  | Bit 9 of the   | data bus, TTB        |  |           |
| D8                 | E1  | 83  | Bit 8 of the   | data bus, TTB        |  |           |
| V <sub>DD</sub>    | E3  | 84  | +5.0 V   |                      |  |           |
|                    |   | TI = TTL i<br>TO = TTL c<br>TTB = bidire<br>TTO = three<br>TUI = TTL i<br>MEMWIN<br>and not for | nput<br>output<br>ctional<br>state TTL outp<br>input (pull-up)<br>is an internal te<br>or use. | ut                   | edance state when idle.<br>ould be considered a floa | ting pin  |
| MICRO              | STANDAR<br>CIRCUIT D                                      |   |  | SIZE<br>A            |  | 5962-89   |
| FENSE SU           | FENSE SUPPLY CENTER COLUMBUS<br>COLUMBUS, OHIO 43216-5000 |   |  |                      | REVISION LEVEL                                       | SHEET     |

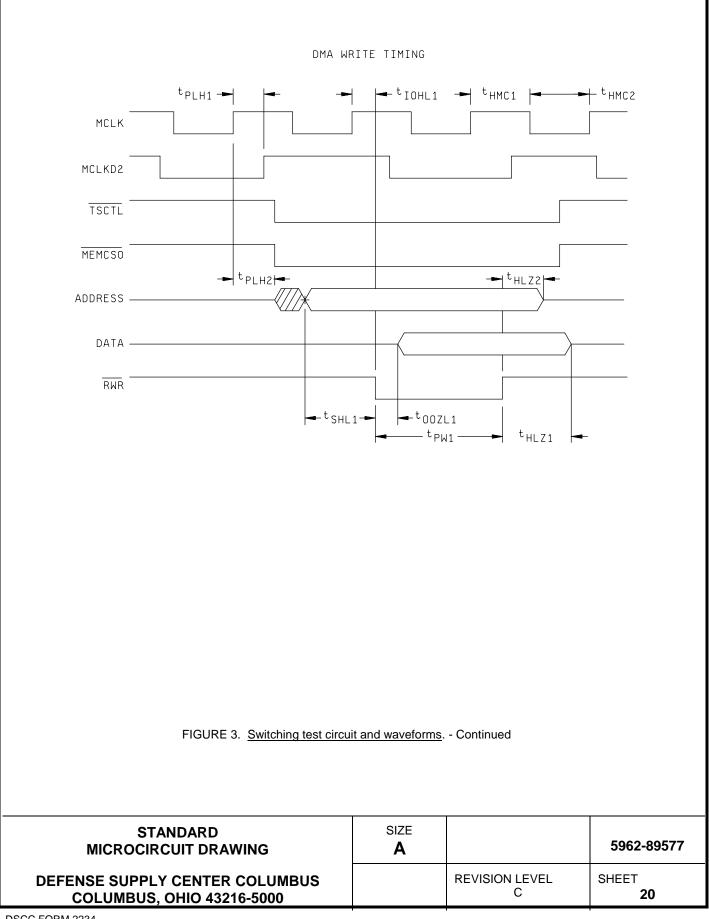


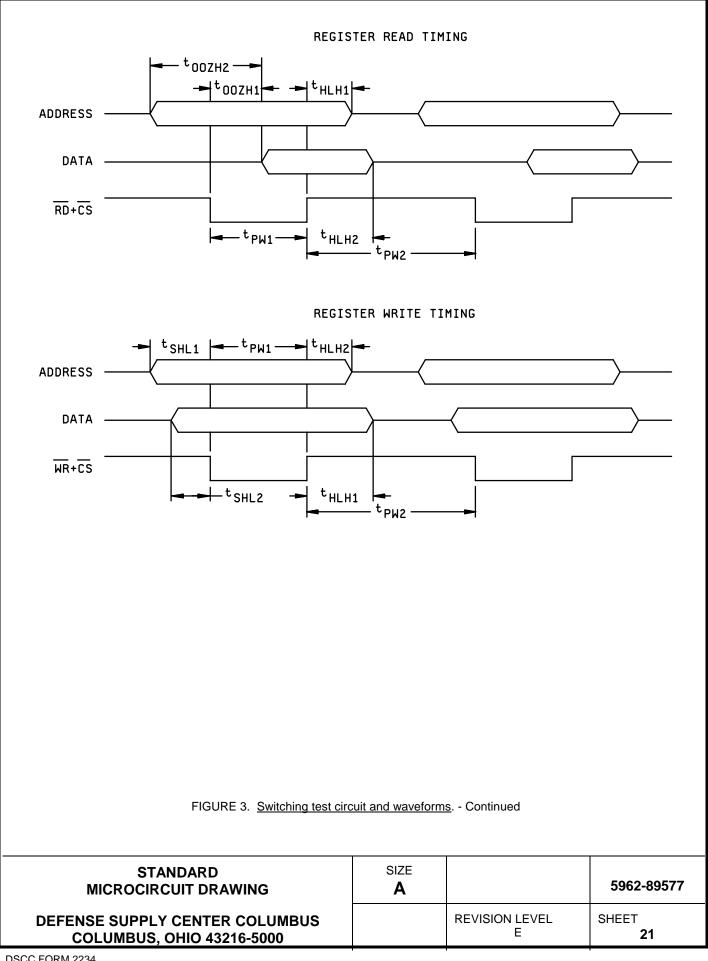


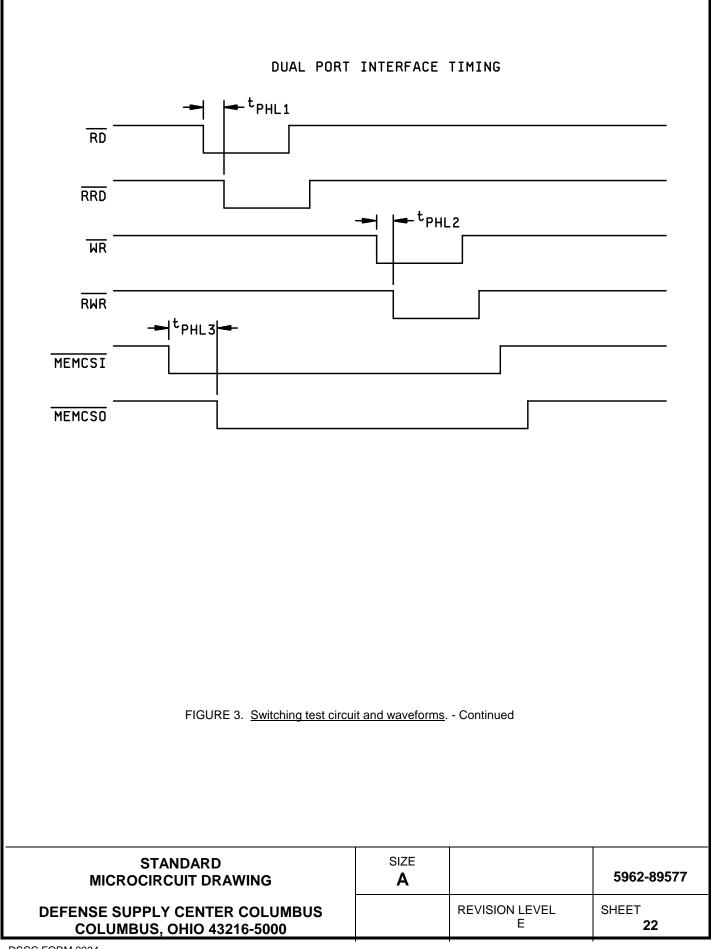
BURST DMA TIMING

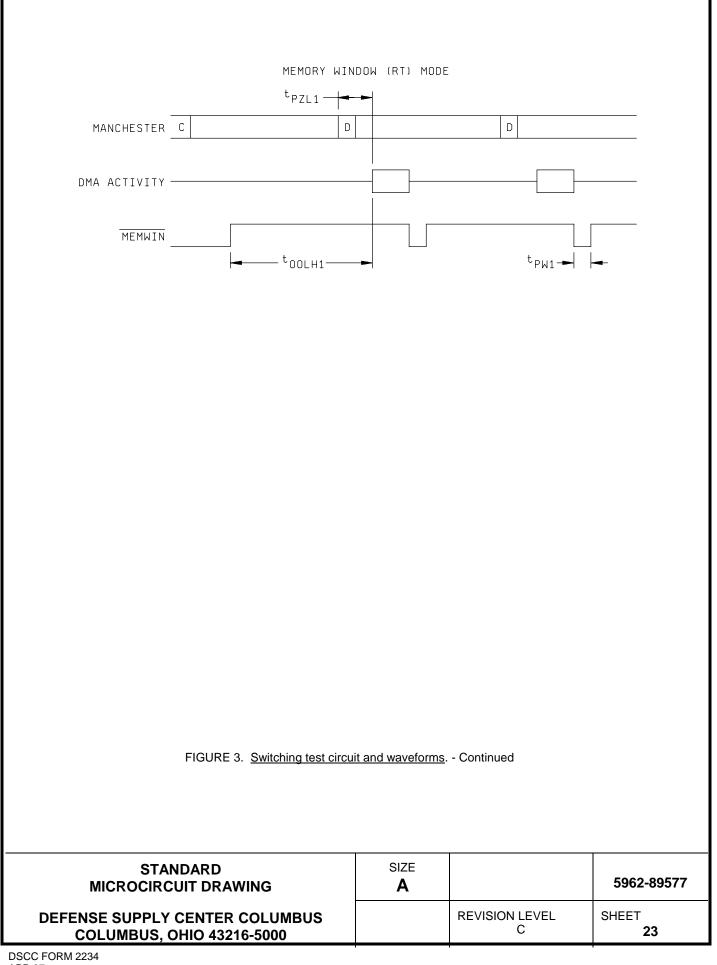


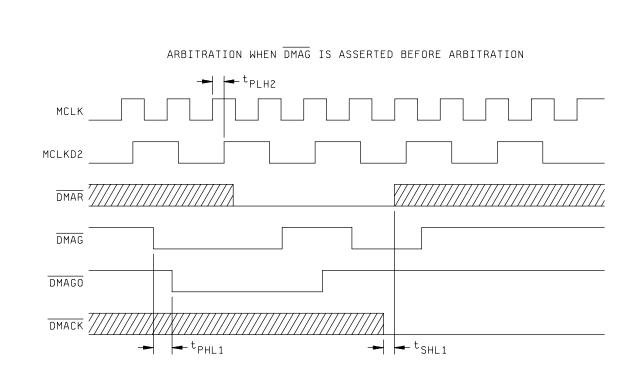


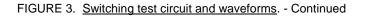




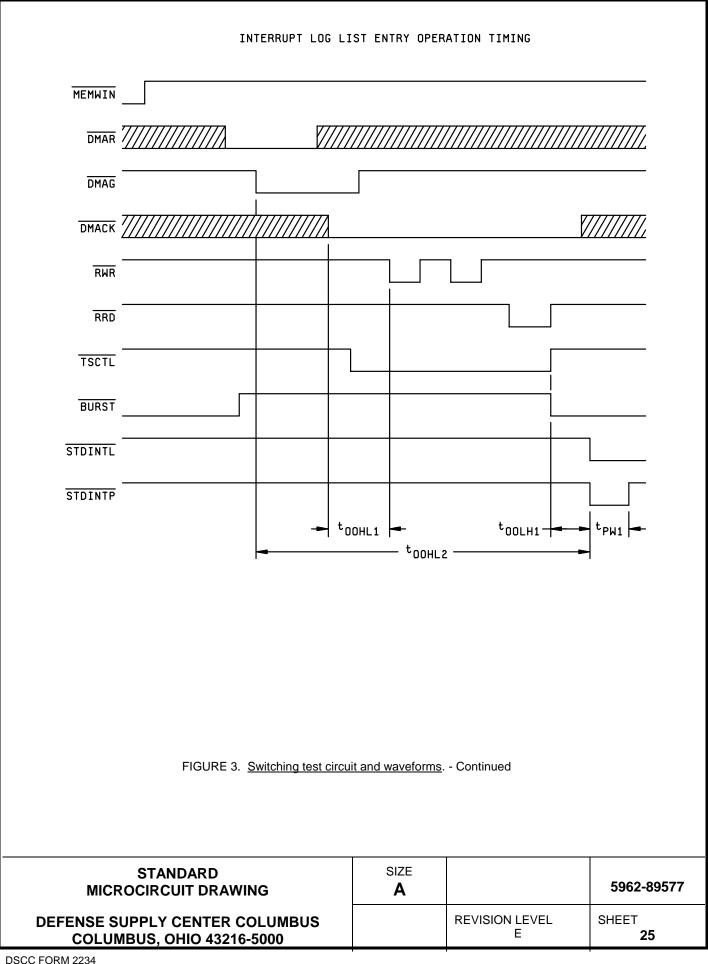








| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br>A |                | 5962-89577 |
|----------------------------------|-----------|----------------|------------|
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| COLUMBUS, OHIO 43216-5000        |           | C              | <b>24</b>  |



| Open  | V <sub>DD</sub> = 5 V ±0.5 V   | Ground  |
|---|--|---|
| 13 (K3), 14 (L2), 17 (L4), 18 (K6),<br>25 (K7), 26 (J7), 27 (L8), 38 (H11),<br>39 (G9), 40 (G10), 41 (G11), 44 (E9),<br>45 (E11), 46 (E10), 47 (F11), 48 (D11),<br>49 (D10), 50 (C11), 51 (B11), 52 (C10),<br>53 (A11), 54 (B10), 55 (B9), 56 (A10),<br>58 (B8), 67 (B5), 68 (A6), 69 (A4),<br>70 (B4), 71 (A3), 73 (B3), 74 (A1),<br>75 (B2), 76 (C2), 77 (B1), 78 (C1), | 10 (J2), 11 (L1), 12 (K2), 23 (L6),<br>24 (L7), 28 (K8), 43 (F9), 57 (A9),<br>59 (A8), 61 (B7), 64 (C6), 84 (E3) | 1 (F3), 2 (F1), 3 (G1), 4 (G2)<br>5 (G3), 6 (H1), 7 (H2), 8 (J1),<br>9 (K1), 15 (L3), 16 (K4), 19 (K5), 20<br>(L5), 21 (J5), 22 (J6), 29 (L9), 30<br>(L10), 31 (K9), 32 (L11),<br>33 (K10), 34 (J10), 35 (K11),<br>36 (J11), 37 (H10), 42 (F10),<br>60 (C7), 62 (A7), 63 (B6), 65 (C5),<br>66 (A5), 72 (A2) |
| 79 (D2), 80 (D1), 81 (F2), 82 (E2),<br>83 (E1)  |  |   |

Pin grid array pin identification is in parenthesis. Flat pack pin numbers is not in parenthesis.

FIGURE 4. Radiation exposure circuit.

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br><b>A</b> |                | 5962-89577 |
|----------------------------------|------------------|----------------|------------|
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| COLUMBUS, OHIO 43216-5000        |                  | C              | <b>26</b>  |

## 4. QUALITY ASSURANCE PROVISIONS

4.1 <u>Sampling and inspection</u>. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.

4.2 <u>Screening</u>. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

#### 4.2.1 Additional criteria for device class M.

- a. Burn-in test, method 1015 of MIL-STD-883.
  - (1) Test condition A or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.
  - (2)  $T_A = +125^{\circ}C$ , minimum.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.

#### 4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 <u>Qualification inspection for device classes Q and V</u>. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 <u>Conformance inspection</u>. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br><b>A</b> |                | 5962-89577 |
|----------------------------------|------------------|----------------|------------|
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# 4.4.1 Group A inspection.

- Tests shall be as specified in table IIA herein. a.
- Subgroups 5 and 6 in table I, method 5005 of table IV method 5010 of MIL-STD-883 shall be omitted. b.
- Subgroup 4 (CIN, COUT and CIO) shall be measured only for the initial test and after process or design changes c. which may affect input/output capacitance. A minimum sample size of 10 devices with zero rejects shall be required.
- d. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the functionality of the device. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device; these tests shall have been fault graded in accordance with MIL-STD-883, test method 5012 (see 1.5 herein).

| Test requirements                                    | Subgroups<br>(in accordance with<br>MIL-STD-883,<br>method 5005, table I) | Subgroups<br>(in accordance with<br>MIL-PRF-38535, table III) |                                   |
|--|---|---|-----------------------------------|
|  | Device<br>class M   | Device<br>class Q   | Device<br>class V                 |
| Interim electrical<br>parameters (see 4.2)           |   |   |                                   |
| Final electrical parameters (see 4.2)                | <u>1</u> / 1, 2, 3, 7, 8, 9,<br>10, 11                                    | <u>1</u> / 1, 2, 3, 7, 8,<br>9, 10, 11                        | <u>2/</u> 3/1,2,3,7,<br>8,9,10,11 |
| Group A test requirements (see 4.4)                  | 1, 2, 3, 4, 7, 8, 9,<br>10, 11  | 1, 2, 3, 4, 7, 8,<br>9, 10, 11                                | 1, 2, 3, 4, 7,<br>8, 9, 10, 11    |
| Group C end-point electrical parameters (see 4.4)    | 1, 2, 7, 8A   | 1, 2, 7, 8A   | 1, 2, 7, 8A<br><u>3</u> /         |
| Group D end-point electrical<br>parameters (see 4.4) | 1, 2, 7 ,8A   | 1, 2, 7, 8A   | 1, 2, 7, 8A                       |
| Group E end-point electrical<br>parameters (see 4.4) | 1, 7, 9   | 1, 7, 9   | 1, 7, 9                           |

TABLE IIA. Electrical test requirements.

1/ PDA applies to subgroup 1. 2/ PDA applies to subgroups 1 and 7.

3/ Delta limits as specified in Table IIB herein shall be required when specified and the Delta values shall be completed with reference to the zero hour electrical parameter.

#### Table IIB. Delta limits

| Parameter        | Condition             | Limits                     |
|------------------|-----------------------|----------------------------|
| Q <sub>IDD</sub> | T <sub>A</sub> = 25°C | ±10% of measured value or  |
|                  |                       | 35 μA whichever is greater |

NOTE: If device is tested at or below 35 µA no deltas are required. Deltas are performed at room temperature.

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|----------------------------------|------------------|----------------|------------|
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| COLUMBUS, OHIO 43216-5000        |                  | E              | <b>28</b>  |

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:

a. Test condition A or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.

b.  $T_A = +125^{\circ}C$ , minimum.

c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.

4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes M, Q, and V shall be as specified in MIL-PRF-38535. End-point electrical parameters shall be as specified in table IIA herein.

4.4.4.1 <u>Total dose irradiation testing</u>. Total dose irradiation testing shall be performed in accordance with MIL-STD-883 method 1019 and as specified herein.

4.4.4.1.1 <u>Accelarated aging test</u>. Accelaerated aging tests shall be performed on all devices requiring a RHA level greater than 5k rads (Si). The post-anneal end-point electrical parameter limits shall be as specified in table IA herein and shall be the pre-irradiation end-point electrical parameter limit at  $25^{\circ}$ C. Testing shall be performed at initial qualification and after any design or process changes which may affect the RHA response of the device.

4.4.4.2 <u>Dose rate induced latchup testing</u>. Dose rate induced latchup testing shall be performed in accoradance with test method 1020 of MIL-STD-883 and as specified herein (see 1.4). Tests shall be performed on devices, SEC, or approved test structures at technology qualification and after any design or process changes which may effect the RHA capability of the process.

4.4.4.3 <u>Dose rate upset testing</u>. Dose rate upset testing shall be performed in accoradance with test method 1021 of MIL-STD-883 and herein (see 1.4).

- a. Transient dose rate upset testing shall be performed at initial qualification and after any design or process changes which may effect the RHA performance of the devices. Test 10 devices with 0 defects unless otherwise specified.
- b. Transient dose rate upset testing for class Q and V devices shall be performed as specified by a TRB approved radiation hardness assurance plan and MIL-PRF-38535.

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|----------------------------------|------------------|----------------|------------|
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| COLUMBUS, OHIO 43216-5000        |                  | E              | 29         |

4.4.4.4 <u>Single event phenomena (SEP)</u>. SEP testing shall be required on class V devices (See 1.4). SEP testing shall be performed on the Standard Evaluation Circuit (SEC) or alternate SEP test vehice as approved by the qualifying activity at initial qualification and after any design or process changes which may affect the upse or latchup characteristics. The recommended test conditions for SEP are as follows:

- a. The ion beam angle of incidence shall be between normal to the die surface and 60° to the normal, inclusive (i.e. 0° ≤ angle ≤ 60°). No shadowing of the ion beam due to fixturing or package related effects is allowed.
- b. The fluence shall be  $\geq 100$  errors or  $\geq 10^6$  ions/cm<sup>2</sup>.
- c. The flux shall be between 10<sup>2</sup> and 10<sup>5</sup> ions/cm<sup>2</sup>/s. The cross-section shall be verified to be flux independent by measuring the cross-section at two flux rates which differ by at least an order of magnitude.
- d. The particle range shall be  $\geq$  20 microns in silicon.
- e. The upset test temperature shall be +25°C and the maximum rated operating temperature ±10°C.
- f. Bias conditions shall be defined by the manufacturer for latchup measurements.
- g. Test four devices with zero failures.
- h. For SEP test limits, see Table IB herein.

#### 5. PACKAGING

5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

#### 6. NOTES

6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.

6.4 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43216-5000, or telephone (614) 692-0547.

6.5 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

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|----------------------------------|------------------|----------------|------------|
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| COLUMBUS, OHIO 43216-5000        |                  | F              | <b>30</b>  |

6.6 Sources of supply.

6.6.1 <u>Sources of supply for device classes Q and V</u>. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.

6.6.2 <u>Approved sources of supply for device class M</u>. Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

6.7 <u>Additional information</u>. A copy of the following additional data shall be maintained and available from the device manufacturer:

a. RHA upset levels.

b. Test conditions (SEP).

c. Number of upsets (SEP).

d. Number of transients (SEP).

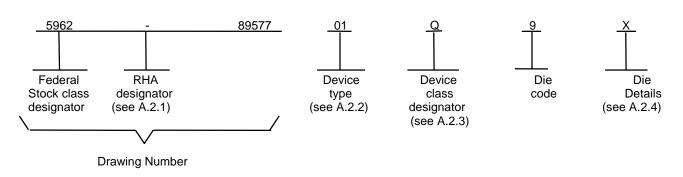
e. Occurrence of latchup (SEP).

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|----------------------------------|-----------|----------------|------------|
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A.1 SCOPE

A.1.1 <u>Scope</u>. This appendix establishes minimum requirements for microcircuit die to be supplied under the Qualified Manufacturers List (QML) Program. QML microcircuit die meeting the requirements of MIL-PRF-38535 and the manufacturers approved QM plan for use in monolithic microcircuits, multichip modules (MCMs), hybrids, electronic modules, or devices using chip and wire designs in accordance with MIL-PRF-38534 are specified herein. Two product assurance classes consisting of military high reliability (device class Q) and space application (device Class V) are reflected in the Part or Identification Number (PIN). When available a choice of Radiation Hardiness Assurance (RHA) levels are reflected in the PIN.

A.1.2 <u>PIN</u>. The PIN shall be as shown in the following example:



A.1.2.1 <u>RHA designator</u>. Device classes Q and V RHA identified die shall meet the MIL-PRF-38535 specified RHA levels. A dash (-) indicates a non-RHA die.

A.1.2.2 <u>Device type(s)</u>. The device type(s) shall identify the circuit function as follows:

| Device type | Generic number | Circuit function                            |
|-------------|----------------|---|
| 01          | UT1553BCRTM    | Bus controller, remote terminal and monitor |

Device requirements documentation

A.1.2.3 Device class designator.

|  | class | Device |
|--|-------|--------|
|--|-------|--------|

Q or V

Certification and qualification to the die requirements of MIL-PRF-38535.

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|----------------------------------|-----------|----------------|------------|
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| COLUMBUS, OHIO 43216-5000        |           | G              | 32         |

A.1.2.4 <u>Die Details</u>. The die details designation shall be a unique letter which designates the die's physical dimensions, bonding pad location(s) and related electrical function(s), interface materials, and other assembly related information, for each product and variant supplied to this appendix.

# A.1.2.4.1 Die Physical dimensions.

| Die Types | Die detail designator | Figure number |
|-----------|-----------------------|---------------|
| 01        | А                     | A-1           |
|           | В                     | B-1           |

A.1.2.4.2 Die Bonding pad locations and Electrical functions.

| Die Types                      | Die detail designator | Figure number |
|--------------------------------|-----------------------|---------------|
| 01                             | A                     | A-1           |
| A.1.2.4.3 Interface Materials. | В                     | B-1           |

| Die Types | Die detail designator | Figure number |
|-----------|-----------------------|---------------|
| 01        | A                     | A-1           |
|           | В                     | B-1           |

A.1.2.4.4 Assembly related information.

| Die Types | Die detail designator | Figure number | Substrate potential     |
|-----------|-----------------------|---------------|-------------------------|
| 01        | А                     | A-1           | Tied to $V_{DD}$        |
|           | В                     | B-1           | Tied to V <sub>SS</sub> |
|           |                       |               |                         |

A.1.3 <u>Absolute maximum ratings</u>. See paragraph 1.3 within the body of this drawing for details.

A.1.4 Recommended operating conditions. See paragraph 1.4 within the body of this drawing for details.

A.2 APPLICABLE DOCUMENTS

A.2.1 <u>Government specifications, standards, bulletin, and handbooks</u>. Unless otherwise specified, the following specifications, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

# SPECIFICATION

DEPARTMENT OF DEFENSE

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

# STANDARDS

DEPARTMENT OF DEFENSE

MIL-STD-883 - Test Method Standard Microcircuits.

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br>A |                | 5962-89577 |
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HANDBOOK

DEPARTMENT OF DEFENSE

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

(Copies of the specification, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity).

A.2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

A.3 REQUIREMENTS

A.3.1 <u>Item Requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit or function as described herein.

A.3.2 <u>Design, construction and physical dimensions</u>. The design, construction and physical dimensions shall be as specified in MIL-PRF-38535 and the manufacturer's QM plan, for device classes Q and V and herein.

A.3.2.1 <u>Die Physical dimensions</u>. The die physical dimensions shall be as specified in A.1.2.4.1 and on figures A-1 and B-1.

A.3.2.2 <u>Die bonding pad locations and electrical functions</u>. The die bonding pad locations and electrical functions shall be as specified in A.1.2.4.2 and on figures A-1and B-1.

A.3.2.3 Interface materials. The interface materials for the die shall be as specified in A.1.2.4.3 and on figures A-1 and B-1.

A.3.2.4 <u>Assembly related information</u>. The assembly related information shall be as specified in A.1.2.4.4 and figures A-1 and B-1.

A.3.2.5 <u>Radiation exposure circuit</u>. The radiation exposure circuit shall be as defined within paragraph 3.2.5 of the body of this document.

A.3.3 <u>Electrical performance characteristics and post- irradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and post-irradiation parameter limits are as specified in table IA of the body of this document.

A.3.4 <u>Electrical test requirements</u>. The wafer probe test requirements shall include functional and parametric testing sufficient to make the packaged die capable of meeting the electrical performance requirements in table IA.

A.3.5 <u>Marking</u>. As a minimum, each unique lot of die, loaded in single or multiple stack of carriers, for shipment to a customer, shall be identified with the wafer lot number, the certification mark, the manufacturer's identification and the PIN listed in 10.2 herein. The certification mark shall be a "QML" or "Q" as required by MIL-PRF-38535.

A.3.6 <u>Certification of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 60.4 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this appendix shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and the requirements herein.

A.3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 shall be provided with each lot of microcircuit die delivered to this drawing.

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#### A.4 QUALITY ASSURANCE PROVISIONS

A.4.1 <u>Sampling and inspection</u>. For device classes Q and V, die sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modifications in the QM plan shall not effect the form, fit or function as described herein.

A.4.2 <u>Screening</u>. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and as defined in the manufacturer's QM plan. As a minimum it shall consist of:

a) Wafer Lot acceptance for Class V product using the criteria defined within MIL-STD-883 TM 5007.

- b) 100% wafer probe (see paragraph 30.4).
- c) 100% internal visual inspection to the applicable class Q or V criteria defined within MIL-STD-883 TM2010 or the alternate procedures allowed within MIL-STD-883 TM5004.

#### A.4.3 Conformance inspection.

A.4.3.1 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be identified as radiation assured (see A.3.5 herein). RHA levels for device classes Q and V shall be as specified in MIL-PRF-38535. End point electrical testing of packaged die shall be as specified in table IIA herein. Group E tests and conditions are as specified within paragraphs 4.4.4.1, 4.4.4.1, 4.4.4.2, 4.4.4.3, and 4.4.4.

#### A.5 DIE CARRIER

A.5.1 <u>Die carrier requirements</u>. The requirements for the die carrier shall be in accordance with the manufacturer's QM plan or as specified in the purchase order by the acquiring activity. The die carrier shall provide adequate physical, mechanical and electrostatic protection.

#### A.6 NOTES

A.6.1 <u>Intended use</u>. Microcircuit die conforming to this drawing are intended for use in microcircuits built in accordance with MIL-PRF-38535 or MIL-PRF-38534 for government microcircuit applications (original equipment), design applications and logistics purposes.

A.6.2 <u>Comments</u>. Comments on this appendix should be directed to DSCC-VA, Columbus, Ohio, 43216-5000 or telephone (614)-692-0547.

A.6.3 <u>Abbreviations, symbols and definitions</u>. The abbreviations, symbols, and definitions used herein are defined with MIL-PRF-38535 and MIL-HDBK-1331.

A.6.4 <u>Sources of Supply for device classes Q and V</u>. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed within QML-38535 have submitted a certificate of compliance (see 30.6 herein) to DSCC-VA and have agreed to this drawing.

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## DIE BONDING PAD LOCATIONS AND ELECTRICAL FUNCTIONS

#### o DIE PHYSICAL DIMENSIONS

Die Size: Die Thickness: 394 mils. x 394 mils. 17.5 +/- 1 mils.

#### **o INTERFACE MATERIALS**

Top Metallization: Si Al Cu 9 kÅ-12.5kÅ

Backside Metallization None: Backgrind

Glassivation Type:

Substrate:

PSG 10 KÅ +/- 2.kÅ

## EPI on single crystal silicon

#### **o ASSEMBLY RELATED INFORMATION**

Thickness

Substrate Potential: Tied to V<sub>DD</sub>

Special assembly instructions:

FIGURE A-1

None

#### DIE BONDING PAD LOCATIONS AND ELECTRICAL FUNCTIONS

#### **o DIE PHYSICAL DIMENSIONS**

Die Size: Die Thickness: 394 mils. x 394 mils. 17.5 +/- 1 mils.

## **o INTERFACE MATERIALS**

| u 9 kÅ-12.5kÅ |
|---------------|
|               |

Backside Metallization None: Backgrind

Glassivation Type:

Substrate:

PSG 10 KÅ +/- 2.kÅ

EPI on single crystal silicon

## o ASSEMBLY RELATED INFORMATION

Thickness

Substrate Potential: Tied to V<sub>SS</sub>

Special assembly instructions:

None

#### FIGURE B-1

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br>A |                | 5962-89577 |
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Die bonding pad locations and electrical functions

| PAD                   | XCENTER                  | YCENTER   | PAD NAME        |
|-----------------------|--------------------------|-----------|-----------------|
| 1                     | -0.0035                  | 0.1840    | V <sub>SS</sub> |
| 2                     | -0.0099                  | 0.1840    | No connect      |
| 3                     | -0.0163                  | 0.1840    | D7              |
| 4                     | -0.0226                  | 0.1840    | No connect      |
| 5                     | -0.0290                  | 0.1840    | No connect      |
| 6                     | -0.0354                  | 0.1840    | D6              |
| 7                     | -0.0418                  | 0.1840    | No connect      |
| 8                     | -0.0482                  | 0.1840    | D5              |
|                       |                          |           |                 |
| 9                     | -0.0545                  | 0.1840    | No connect      |
| 10                    | -0.0609                  | 0.1840    | D4              |
| 11                    | -0.0673                  | 0.1840    | No connect      |
| 12                    | -0.0737                  | 0.1840    | No connect      |
| 13                    | -0.0800                  | 0.1840    | No connect      |
| 14                    | -0.0864                  | 0.1840    | D3              |
| 15                    | -0.0928                  | 0.1840    | No connect      |
| 16                    | -0.0992                  | 0.1840    | D2              |
|                       |                          |           |                 |
| 17                    | -0.1056                  | 0.1840    | No connect      |
| 18                    | -0.1119                  | 0.1840    | D1              |
| 19                    | -0.1183                  | 0.1840    | No connect      |
| 20                    | -0.1247                  | 0.1840    | No connect      |
| 21                    | -0.1311                  | 0.1840    | No connect      |
| 22                    | -0.1374                  | 0.1840    | D0              |
| 23                    | -0.1438                  | 0.1840    | No connect      |
|                       |                          |           |                 |
| 24                    | -0.1502                  | 0.1840    | MRST            |
| 25                    | -0.1566                  | 0.1840    | No connect      |
| 26                    | -0.1630                  | 0.1840    | BCRTSEL         |
| 27                    | -0.1743                  | 0.1840    | No connect      |
| 28                    | -0.1904                  | 0.1676    | No connect      |
| 29                    | -0.1904                  | 0.1564    | LOCK            |
| 30                    | -0.1904                  | 0.1500    | No connect      |
| 31                    | -0.1904                  | 0.1436    | TAZ             |
|                       |                          |           |                 |
| 32                    | -0.1904                  | 0.1372    | No connect      |
| 33                    | -0.1904                  | 0.1308    | TA0             |
| 34                    | -0.1904                  | 0.1245    | No connect      |
| 35                    | -0.1904                  | 0.1181    | No connect      |
| 36                    | -0.1904                  | 0.1117    | No connect      |
| 37                    | -0.1904                  | 0.1053    | RAZ             |
| 38                    | -0.1904                  | 0.0990    | No connect      |
| 39                    | -0.1904                  | 0.0926    | RAO             |
|                       |                          |           |                 |
| 40                    | -0.1904                  | 0.0862    | No connect      |
| 41                    | -0.1904                  | 0.0798    | TBZ             |
| 42                    | -0.1904                  | 0.0734    | No connect      |
| 43                    | -0.1904                  | 0.0671    | TB0             |
| 44                    | -0.1904                  | 0.0607    | No connect      |
| 45                    | -0.1904                  | 0.0543    | RBZ             |
| 46                    | -0.1904                  | 0.0479    | No connect      |
|                       |                          |           |                 |
| 47                    | -0.1904                  | 0.0416    | No connect      |
| 48                    | -0.1904                  | 0.0352    | RB0             |
| 49                    | -0.1904                  | 0.0288    | No connect      |
| 50                    | -0.1904                  | 0.0224    | MHX12           |
|                       |                          |           |                 |
| The die center is the | coordinate origin (0,0). |           |                 |
|                       | F                        | ïgure A-1 |                 |
|                       | F                        | igure A-1 |                 |
|                       | NDARD                    | SIZE      | 5               |
| MICROCIRC             |                          | A         | 3               |

Die bonding pad locations and electrical functions

| PAD                     | XCENTER                 | YCENTER  | PAD NAME        |
|-------------------------|-------------------------|----------|-----------------|
| 51                      | -0.1904                 | 0.0160   | No connect      |
| 52                      | -0.1904                 | 0.0097   | No connect      |
|                         |                         |          |                 |
| 53                      | -0.1904                 | 0.0033   | V <sub>ss</sub> |
| 54                      | -0.1904                 | -0.0031  | V <sub>DD</sub> |
| 55                      | -0.1904                 | -0.0095  | No connect      |
| 56                      | -0.1904                 | -0.0158  | No connect      |
| 57                      | -0.1904                 | -0.0222  | No connect      |
|                         |                         |          |                 |
| 58                      | -0.1904                 | -0.0286  | EXTOVR          |
| 59                      | -0.1904                 | -0.0350  | No connect      |
| 60                      | -0.1904                 | -0.0414  | No connect      |
| 61                      | -0.1904                 | -0.0477  | TIMERON         |
| 62                      | -0.1904                 | -0.0541  | No connect      |
|                         |                         |          |                 |
| 63                      | -0.1904                 | -0.0605  | CHA/B           |
| 64                      | -0.1904                 | -0.0669  | No connect      |
| 65                      | -0.1904                 | -0.0732  | No connect      |
| 66                      | -0.1904                 | -0.0796  | No connect      |
| 00                      | 0.1004                  | -0.0730  |                 |
| 67                      | -0.1904                 | -0.0860  | COMSTR          |
| 68                      | -0.1904                 | -0.0924  | No connect      |
| 69                      | -0.1904                 | -0.0988  | RTA0            |
|                         |                         |          |                 |
| 70                      | -0.1904                 | -0.1051  | No connect      |
| 71                      | -0.1904                 | -0.1115  | RTA1            |
| 72                      | -0.1904                 | -0.1179  | No connect      |
| 73                      | -0.1904                 | -0.1243  | RTA2            |
|                         |                         |          |                 |
| 74                      | -0.1904                 | -0.1307  | No connect      |
| 75                      | -0.1904                 | -0.1370  | No connect      |
| 76                      | -0.1904                 | -0.1434  | No connect      |
| 77                      | -0.1904                 | -0.1498  | RTA3            |
| 78                      | -0.1904                 | -0.1562  | No connect      |
|                         |                         |          |                 |
| 79                      | -0.1905                 | -0.1625  | RTA4            |
| 80                      | -0.1904                 | -0.1743  | No connect      |
| 81                      | -0.1743                 | -0.1905  | No connect      |
| 82                      | -0.1629                 | -0.1905  | RTPTY           |
|                         |                         |          |                 |
| 83                      | -0.1566                 | -0.1905  | No connect      |
| 84                      | -0.1502                 | -0.1905  | AO              |
| 85                      | -0.1438                 | -0.1905  | No connect      |
| 86                      | -0.1374                 | -0.1905  | No connect      |
|                         |                         |          |                 |
| 87                      | -0.1311                 | -0.1905  | No connect      |
| 88                      | -0.1247                 | -0.1905  | A1              |
| 89                      | -0.1183                 | -0.1905  | No connect      |
| 90                      | -0.1119                 | -0.1905  | A2              |
| 91                      | -0.1056                 | -0.1905  | No connect      |
|                         |                         |          |                 |
| 92                      | -0.0992                 | -0.1905  | A3              |
| 93                      | -0.0928                 | -0.1905  | No connect      |
| 94                      | -0.0864                 | -0.1905  | A4              |
| 95                      | -0.0800                 | -0.1905  | No connect      |
| 90                      | -0.0000                 | -0.1905  | No connect      |
|                         |                         |          |                 |
|                         |                         |          |                 |
|                         |                         |          |                 |
|                         |                         |          |                 |
|                         |                         | 1        | <u> </u>        |
| ne die center is the co | oordinate origin (0,0). |          |                 |
|                         | (0,0).                  |          |                 |
|                         |                         |          |                 |
|                         |                         |          |                 |
|                         | Fic                     | jure A-1 |                 |

| STANDARD<br>MICROCIRCUIT DRAWING | SIZE<br>A |                | 5962-89577 |
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Die bonding pad locations and electrical functions

| PAD                         | XCENTER                 | YCENTER   | PAD NAME        |
|-----------------------------|-------------------------|-----------|-----------------|
| 96                          | -0.0737                 | -0.1905   | No connect      |
| 97                          | -0.0673                 | -0.1905   | No connect      |
| 98                          | -0.0609                 | -0.1905   | A5              |
|                             |                         |           |                 |
| 99                          | -0.0545                 | -0.1905   | No connect      |
| 100                         | -0.0482                 | -0.1905   | A6              |
| 101                         | -0.0418                 | -0.1905   | No connect      |
| 102                         | -0.0354                 | -0.1905   | A7              |
| 103                         | -0.0290                 | -0.1905   | No connect      |
|                             |                         |           |                 |
| 104                         | -0.0226                 | -0.1905   | BCRTMSEL        |
| 105                         | -0.0163                 | -0.1905   | No connect      |
| 106                         | -0.0099                 | -0.1905   | V <sub>SS</sub> |
| 107                         | -0.0035                 | -0.1905   | V <sub>DD</sub> |
| 108                         | 0.0029                  | -0.1905   | No connect      |
|                             |                         |           |                 |
| 109                         | 0.0093                  | -0.1905   | No connect      |
| 110                         | 0.0156                  | -0.1905   | A8              |
| 111                         | 0.0220                  | -0.1905   | No connect      |
| 112                         | 0.0284                  | -0.1905   | A9              |
|                             |                         |           |                 |
| 113                         | 0.0348                  | -0.1905   | No connect      |
| 114                         | 0.0411                  | -0.1905   | A10             |
| 115                         | 0.0475                  | -0.1905   | No connect      |
| 116                         | 0.0539                  | -0.1905   | A11             |
| 117                         | 0.0603                  |           | No connect      |
|                             |                         | -0.1905   |                 |
| 118                         | 0.0667                  | -0.1905   | No connect      |
| 119                         | 0.0730                  | -0.1905   | No connect      |
| 120                         | 0.0794                  | -0.1905   | A12             |
| 121                         | 0.0858                  | -0.1905   | No connect      |
| 122                         | 0.0922                  | -0.1905   | A13             |
|                             |                         |           |                 |
| 123                         | 0.0985                  | -0.1905   | No connect      |
| 124                         | 0.1049                  | -0.1905   | A14             |
| 125                         | 0.1113                  | -0.1905   | No connect      |
| 126                         | 0.1177                  | -0.1905   | No connect      |
|                             |                         |           |                 |
| 127                         | 0.1241                  | -0.1905   | No connect      |
| 128                         | 0.1305                  | -0.1905   | A15             |
| 129                         | 0.1369                  | -0.1904   | No connect      |
| 130                         | 0.1433                  | -0.1904   | RWR             |
| 131                         | 0.1497                  | -0.1904   | No connect      |
| 100                         | 0.4500                  | 0.4005    |                 |
| 132                         | 0.1560                  | -0.1905   | RRD             |
| 133                         | 0.1676                  | -0.1905   | No connect      |
| 134                         | 0.1840                  | -0.1743   | No connect      |
| 135                         | 0.1840                  | -0.1624   | MEMSCO          |
| 136                         | 0.1840                  | -0.1562   |                 |
|                             |                         |           | No connect      |
| 137                         | 0.1840                  | -0.1498   | TSCTL           |
| 138                         | 0.1840                  | -0.1434   | No connect      |
| 139                         | 0.1840                  | -0.1370   | No connect      |
| 140                         | 0.1840                  | -0.1307   | No connect      |
|                             |                         |           | DMAR            |
| 141                         | 0.1840                  | -0.1243   |                 |
| 142                         | 0.1840                  | -0.1179   | No connect      |
|                             |                         |           |                 |
|                             |                         |           |                 |
| E: The die center is the co | oordinate origin (0,0). |           |                 |
|                             |                         |           |                 |
|                             | F                       | igure A-1 |                 |
|                             |                         |           |                 |
|                             |                         |           |                 |

Die bonding pad locations and electrical functions

| PAD                           | XCENTER               | YCENTER | PAD NAME            |             |
|-------------------------------|-----------------------|---------|---------------------|-------------|
| 143                           | 0.1840                | -0.1115 | DMAG                |             |
| 144                           | 0.1840                | -0.1051 | No connect          | t           |
| 145                           | 0.1840                | -0.0988 | No connect          | t           |
| 146                           | 0.1840                | -0.0924 | No connect          | t           |
| 147                           | 0.1840                | -0.0860 | DMACK               |             |
| 148                           | 0.1840                | -0.0796 | No connect          | t           |
| 149                           | 0.1840                | -0.0732 | MEMCSI              | •           |
| 150                           | 0.1840                | -0,0669 | No connect          | t           |
|                               | 0.1010                | 0,0000  |                     |             |
| 151                           | 0.1840                | -0.0605 | WR                  |             |
| 152                           | 0.1840                | -0.0541 | No connect          |             |
| 153                           | 0.1840                | -0.0477 | No connect          | t           |
| 154                           | 0.1840                | -0.0414 |                     |             |
| 155                           | 0.1840                | -0.0350 | No connect          | t           |
| 156                           | 0.1840                | -0.0286 | cs                  |             |
| 157                           | 0.1840                | -0.0222 | No connect          | t           |
| 158                           | 0.1840                | -0.0158 | No connect          |             |
|                               |                       |         |                     |             |
| 159                           | 0.1840                | -0.0095 | V <sub>ss</sub>     |             |
| 160                           | 0.1840                | -0.0031 | V <sub>DD</sub>     |             |
| 161                           | 0.1840                | 0.0033  | No connect          |             |
| 162                           | 0.1840                | 0.0097  | No connect          |             |
| 163                           | 0.1840                | 0.0160  | No connect          | t           |
| 164                           | 0.1840                | 0.0224  | MCLK                |             |
| 165                           | 0.1840                | 0.0288  | No connect          | t           |
| 166                           | 0.1840                | 0.0352  | AEN                 | -           |
| 167                           | 0.1840                | 0.0416  | No connect          | •           |
| 168                           | 0.1840                | 0.0479  | No connect          |             |
|                               |                       |         |                     | l           |
| 169                           | 0.1840                | 0.0543  | DMAGO               |             |
| 170                           | 0.1840                | 0.0607  | No connect          | t           |
| 171                           | 0.1840                | 0.0671  | STDINTL             |             |
| 172                           | 0.1840                | 0.0734  | No connect          | t           |
| 173                           | 0.1840                | 0.0798  | STDINTP             |             |
| 174                           | 0.1840                | 0.0862  | No connect          | t           |
| 175                           | 0.1840                | 0.0926  | HPINT               | -           |
| 176                           | 0.1840                | 0.0990  | No connect          | •           |
|                               |                       |         |                     |             |
| 177                           | 0.1840                | 0.1053  | No connect          |             |
| 178                           | 0.1840                | 0.1117  | No connect          | t           |
| 179                           | 0.1840                | 0.1181  | MCLKD2              |             |
| 180                           | 0.1840                | 0.1245  | No connect          | t           |
| 181                           | 0.1840                | 0.1308  | SSYSF               |             |
| 182                           | 0.1840                | 0.1372  | No connect          | t           |
| 183                           | 0.1840                | 0.1436  | TEST                |             |
| 184                           | 0.1840                | 0.1500  | No connect          | t I         |
| 185                           | 0.1840                | 0.1564  | BURST               | •           |
|                               |                       |         |                     |             |
| 186                           | 0.1840                | 0.1676  | No connect          |             |
| 187                           | 0.1676                | 0.1840  | No connect          | t           |
|                               |                       |         |                     |             |
|                               |                       |         |                     |             |
| L The discourt of the         |                       |         | 1                   |             |
| E: The die center is the coor | rainate origin (0,0). |         |                     |             |
|                               |                       |         |                     |             |
|                               | Figu                  | ure A-1 |                     |             |
|                               |                       |         |                     |             |
|                               |                       |         |                     |             |
| STAND                         | ARD                   | SIZE    |                     |             |
|                               |                       | Α       |                     | 5962-8957   |
| MICROCIRCUI                   | DRAWING               |         |                     |             |
|                               |                       |         |                     |             |
| DEFENSE SUPPLY CE             | NTER COLUMBUS         |         | REVISION LEVEL      | SHEET       |
|                               | NTER COLUMBUS         |         | REVISION LEVEL<br>G | SHEET<br>40 |

Die bonding pad locations and electrical functions

| PAD | XCENTER | YCENTER | PAD NAME        |
|-----|---------|---------|-----------------|
| 188 | 0.1559  | 0.1840  | BCRTF           |
| 189 | 0.1496  | 0.1840  | No connect      |
| 190 | 0.1432  | 0.1840  | D15             |
| 191 | 0.1368  | 0.1840  | No connect      |
| 192 | 0.1304  | 0.1840  | D14             |
| 193 | 0.1241  | 0.1840  | No connect      |
| 194 | 0.1177  | 0.1840  | No connect      |
| 195 | 0.1113  | 0.1840  | No connect      |
| 196 | 0.1049  | 0.1840  | D13             |
| 197 | 0.0985  | 0.1840  | No connect      |
| 198 | 0.0922  | 0.1840  | D12             |
| 199 | 0.0858  | 0.1840  | No connect      |
| 200 | 0.0794  | 0.1840  | D11             |
| 201 | 0.0730  | 0.1840  | No connect      |
| 202 | 0.0667  | 0.1840  | No connect      |
| 203 | 0.0603  | 0.1840  | No connect      |
| 204 | 0.0539  | 0.1840  | D10             |
| 205 | 0.0475  | 0.1840  | No connect      |
| 206 | 0.0411  | 0.1840  | D9              |
| 207 | 0.0348  | 0.1840  | No connect      |
| 208 | 0.0284  | 0.1840  | No connect      |
| 209 | 0.0220  | 0.1840  | D8              |
| 210 | 0.0156  | 0.1840  | No connect      |
| 211 | 0.0093  | 0.1840  | No connect      |
| 212 | 0.0029  | 0.1840  | V <sub>DD</sub> |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         | 1               |

NOTE: The die center is the coordinate origin (0,0).

Figure A-1

# STANDARD<br/>MICROCIRCUIT DRAWINGSIZE<br/>ASIZE<br/>A5962-89577DEFENSE SUPPLY CENTER COLUMBUS<br/>COLUMBUS, OHIO 43216-5000REVISION LEVEL<br/>GSHEET<br/>41

Die bonding pad locations and electrical functions

| PAD                                 | XCENTER      | YCENTE |                 |        |
|-------------------------------------|--------------|--------|-----------------|--------|
| 1                                   | 165          | 185.9  | V <sub>SS</sub> |        |
| 2                                   | 158.7        | 185.9  | V <sub>DQ</sub> |        |
| 3                                   | 152.4        | 185.9  | No Connec       | t      |
| 4                                   | 146.1        | 185.9  | BF              |        |
| 5                                   | 139.8        | 185.9  | No Connec       | t      |
| 6                                   | 133.5        | 185.9  | D15             |        |
| 7                                   | 127.2        | 185.9  | D14             |        |
| 8                                   | 120.9        | 185.9  | No Connec       | t I    |
|                                     | 114.6        | 185.9  | No Connec       |        |
| 9                                   |              |        |                 |        |
| 10                                  | 108.3        | 185.9  | No Connec       | τ      |
| 11                                  | 102          | 185.9  | D13             |        |
| 12                                  | 95.7         | 185.9  | No Connec       | t      |
| 13                                  | 89.4         | 185.9  | D12             |        |
| 14                                  | 83.1         | 185.9  | D11             |        |
| 15                                  | 76.8         | 185.9  | V <sub>SQ</sub> |        |
| 16                                  | 70.5         | 185.9  | No Connec       | t      |
| 17                                  | 64.2         | 185.9  | No Connec       |        |
| 18                                  | 57.9         | 185.9  | No Connec       |        |
| 19                                  | 51.6         | 185.9  | D10             |        |
|                                     |              |        |                 | *      |
| 20                                  | 45.3         | 185.9  | No Connec       | u l    |
| 21                                  | 39           | 185.9  | D9              | .      |
| 22                                  | 32.7         | 185.9  | No Connec       | t      |
| 23                                  | 26.4         | 185.9  | D8              |        |
| 24                                  | 20.1         | 185.9  | No Connec       | t      |
| 25                                  | 13.8         | 185.9  | V <sub>DQ</sub> |        |
| 26                                  | 7.5          | 185.9  | V <sub>SS</sub> |        |
| 27                                  | 1.2          | 185.9  | V <sub>DD</sub> |        |
| 28                                  | -5.1         | 185.9  | V <sub>SQ</sub> |        |
| 29                                  | -11.4        |        | No Connec       | +      |
|                                     |              | 185.9  |                 |        |
| 30                                  | -17.7        | 185.9  | No Connec       |        |
| 31                                  | -24          | 185.9  | No Connec       | τ      |
| 32                                  | -30.3        | 185.9  | D7              | .      |
| 33                                  | -36.6        | 185.9  | No Connec       | t      |
| 34                                  | -42.9        | 185.9  | D6              |        |
| 35                                  | -49.2        | 185.9  | No Connec       | t      |
| 36                                  | -55.5        | 185.9  | D5              |        |
| 37                                  | -61.8        | 185.9  | No Connec       | t I    |
| 38                                  | -68.1        | 185.9  | No Connec       |        |
| 39                                  | -74.4        | 185.9  | V <sub>SQ</sub> | -      |
| 40                                  | -80.7        | 185.9  | D4              |        |
| 40 41                               | -87          | 185.9  |                 | +      |
|                                     |              |        | No Connec       | u l    |
| 42                                  | -93.3        | 185.9  | D3              | .      |
| 43                                  | -99.6        | 185.9  | No Connec       | τ      |
| 44                                  | 105.9        | 185.9  | D2              |        |
| 45                                  | 112.2        | 185.9  | No Connec       |        |
| 46                                  | 118.5        | 185.9  | No Connec       | t      |
| 47                                  | 124.8        | 185.9  | D0              |        |
| 48                                  | 131.1        | 185.9  | MRST            |        |
| 49                                  | 137.4        | 185.9  | BCRTSEL         |        |
| 50                                  | 143.7        | 185.9  | No Connec       |        |
|                                     | 170.1        | 105.9  | No Connec       |        |
|                                     |              |        |                 |        |
| I                                   |              | 1      | I               |        |
| The die center is the coordinate of | riain (0.0). |        |                 |        |
|                                     |              |        |                 |        |
|                                     |              |        |                 |        |
|                                     |              |        |                 |        |
|                                     |              |        |                 |        |
|                                     | Figu         | re B-1 |                 |        |
| <b></b>                             | 5            | 1      |                 | [      |
| STANDARD                            |              | SIZE   |                 | 5962-8 |
| MICROCIRCUIT DRAV                   | VING         | Α      |                 | 0002-0 |
|                                     |              |        |                 |        |
| DEFENSE SUPPLY CENTER C             |              |        | REVISION LEVEL  | SHEET  |
|                                     |              |        |                 |        |

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COLUMBUS, OHIO 43216-5000

Die bonding pad locations and electrical functions

| XCENTER<br>150<br>156.3<br>162.6<br>168.9<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6 | YCENTER<br>185.9<br>185.9<br>185.9<br>170.2<br>163.9<br>157.4<br>151.1<br>144.8  | PAD NAME<br>No Connect<br>V <sub>SQ</sub><br>V <sub>SS</sub><br>V <sub>DD</sub><br>V <sub>DQ</sub><br>No Connect<br>No Connect<br>LOCK  |  |
|---|--|---|--|
| 156.3<br>162.6<br>168.9<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6   | 185.9<br>185.9<br>170.2<br>163.9<br>157.4<br>151.1<br>144.8  | No Connect<br>$V_{SQ}$<br>$V_{SS}$<br>$V_{DD}$<br>$V_{DQ}$<br>No Connect<br>No Connect  |  |
| 162.6<br>168.9<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6  | 185.9<br>185.9<br>170.2<br>163.9<br>157.4<br>151.1<br>144.8  | $V_{SQ} \\ V_{SS} \\ V_{DD} \\ V_{DQ} \\ No \ Connect $ |  |
| 168.9<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6   | 185.9<br>170.2<br>163.9<br>157.4<br>151.1<br>144.8   | $V_{SS}$ $V_{DD}$ $V_{DQ}$ No Connect No Connect  |  |
| 184.6<br>184.6<br>184.6<br>184.6<br>184.6   | 170.2<br>163.9<br>157.4<br>151.1<br>144.8  | V <sub>DD</sub><br>V <sub>DQ</sub><br>No Connect<br>No Connect  |  |
| 184.6<br>184.6<br>184.6<br>184.6  | 163.9<br>157.4<br>151.1<br>144.8   | V <sub>DQ</sub><br>No Connect<br>No Connect   |  |
| 184.6<br>184.6<br>184.6   | 157.4<br>151.1<br>144.8  | No Connect<br>No Connect  |  |
| 184.6<br>184.6  | 151.1<br>144.8   | No Connect  |  |
| 184.6   | 144.8  |   |  |
|   |  |   |  |
|   |  | LUCK  |  |
|   | 138.5  | No Connect  |  |
| 184.6   | 132.2  | TAZ   |  |
| 184.6   | 125.9  | TAO   |  |
|   |  |   |  |
|   | 119.0  |   |  |
|   |  |   |  |
|   |  |   |  |
| 184.6   | 100.8  | No Connect  |  |
|   |  | RAO   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
| 184.6   | 56.7   | No Connect  |  |
|   |  | RBZ   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  | V <sub>DQ</sub>   |  |
| 184.6   | 12.6   | V <sub>DD</sub>   |  |
| 184.6   | 6.3  | Vss   |  |
|   |  | Veo   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
| 184.6   | -31.5  | EXTOVR  |  |
| 184.6   | -37.8  | No Connect  |  |
| 184.6   |  | TIMERON   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
| 184.6   | -75.6  | CMDST   |  |
| 184.6   | -81.9  |   |  |
|   |  | No Connect  |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
|   |  |   |  |
| 184.6   | -113.4   | No Connect  |  |
|   |  |   |  |
|   |  |   |  |
|   | 184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>184.6<br>18 | 184.6 $119.6$ $184.6$ $107.1$ $184.6$ $100.8$ $184.6$ $94.5$ $184.6$ $88.2$ $184.6$ $81.9$ $184.6$ $69.3$ $184.6$ $69.3$ $184.6$ $63$ $184.6$ $56.7$ $184.6$ $56.7$ $184.6$ $50.4$ $184.6$ $50.4$ $184.6$ $37.8$ $184.6$ $25.2$ $184.6$ $25.2$ $184.6$ $12.6$ $184.6$ $12.6$ $184.6$ $-6.3$ $184.6$ $-12.6$ $184.6$ $-52.2$ $184.6$ $-31.5$ $184.6$ $-31.5$ $184.6$ $-37.8$ $184.6$ $-50.4$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-56.7$ $184.6$ $-88.2$ $184.6$ $-88.2$ $184.6$ $-88.2$ $184.6$ $-88.2$ $184.6$ $-94.5$ $184.6$ $-100.8$ $184.6$ $-100.8$ $184.6$ $-107.1$  | 184.6         119.6         No Connect           184.6         113.3         RAZ           184.6         107.1         No Connect           184.6         100.8         No Connect           184.6         94.5         RAO           184.6         88.2         No Connect           184.6         81.9 $V_{so}$ 184.6         63.3         TBO           184.6         63.3         No Connect           184.6         63.3         No Connect           184.6         63.3         No Connect           184.6         56.7         No Connect           184.6         50.4         RBZ           184.6         31.5         MH212           184.6         31.5         MH212           184.6         18.9         V_{bo}           184.6         18.9         V_{bo}           184.6         -12.6         No Connect           184.6         -12.6         No Connect           184.6         -6.3         No Connect           184.6         -6.3         No Connect           184.6         -6.3         No Connect           184.6         -6.3 |

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DEFENSE SUPPLY CENTER COLUMBUS

COLUMBUS, OHIO 43216-5000

Die bonding pad locations and electrical functions

| 101 | XCENTER                    | YCENTER  | PAD NAME        |
|-----|----------------------------|----------|-----------------|
|     | 184.6                      | -119.7   | RTA2            |
| 102 | 184.6                      | -126     | RTA3            |
| 103 | 184.6                      | -132.3   | RTA4            |
| 104 | 184.6                      | -138.6   | No Connect      |
| 105 | 184.6                      | -144.9   | No Connect      |
| 106 | 184.6                      | -151.2   | No Connect      |
|     |                            |          |                 |
| 107 | 184.6                      | -157.5   | No Connect      |
| 108 | 184.6                      | -164     | V <sub>SQ</sub> |
| 109 | 184.6                      | -170.3   | V <sub>DD</sub> |
| 110 | 168.9                      | -186     | V <sub>SS</sub> |
| 111 | 162.6                      | -186     | V <sub>DQ</sub> |
| 112 | 156.3                      | -186     | No Connect      |
| 113 | 150                        | -186     | RTPTY           |
| 114 | 143.7                      | -186     | No Connect      |
|     |                            |          |                 |
| 115 | 137.4                      | -186     | AO              |
| 116 | 131.1                      | -186     | No Connect      |
| 117 | 124.8                      | -186     | A1              |
| 118 | 118.5                      | -186     | No Connect      |
| 119 | 112.2                      | -186     | No Connect      |
| 120 | 105.9                      | -186     | No Connect      |
| 120 | -99.6                      | -186     | A2              |
|     |                            |          | No Connect      |
| 122 | -93.3                      | -186     |                 |
| 123 | -87                        | -186     | No Connect      |
| 124 | -80.7                      | -186     | V <sub>SQ</sub> |
| 125 | -74.4                      | -186     | A4              |
| 126 | -68.1                      | -186     | No Connect      |
| 127 | -61.8                      | -186     | No Connect      |
| 128 | -55.5                      | -186     | A5              |
| 129 | -49.2                      | -186     | No Connect      |
|     |                            |          |                 |
| 130 | -42.9                      | -186     | No Connect      |
| 131 | -36.6                      | -186     | A6              |
| 132 | -30.3                      | -186     | A7              |
| 133 | -24                        | -186     | No Connect      |
| 134 | -17.7                      | -186     | V <sub>DQ</sub> |
| 135 | -11.4                      | -186     | V <sub>ss</sub> |
| 136 | -5.1                       | -186     | V <sub>DD</sub> |
|     |                            |          |                 |
| 137 | 1.2                        | -186     | V <sub>SQ</sub> |
| 138 | 7.5                        | -186     | No Connect      |
| 139 | 13.8                       | -186     | No Connect      |
| 140 | 20.1                       | -186     | No Connect      |
| 141 | 26.4                       | -186     | A8              |
| 142 | 32.7                       | -186     | No Connect      |
| 143 | 39                         | -186     | A9              |
| 144 | 45.3                       | -186     | No Connect      |
|     |                            |          |                 |
| 145 | 51.6                       | -186     | A10             |
| 146 | 57.9                       | -186     | No Connect      |
| 147 | 64.2                       | -186     | No Connect      |
| 148 | 70.5                       | -186     | V <sub>SQ</sub> |
| 149 | 76.8                       | -186     | A11             |
| 150 | 83.1                       | -186     | No Connect      |
| -   |                            |          |                 |
|     | $\sim$                     | 1        |                 |
|     | e coordinate origin (0,0). | gure B-1 |                 |

DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43216-5000  
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Die bonding pad locations and electrical functions

| [    | PAD                     | XCENTER                  | YCENTE         |                              | E          |
|------|-------------------------|--------------------------|----------------|------------------------------|------------|
|      | 151                     | 89.4                     | -186           | A12                          |            |
|      | 152<br>153              | 95.7<br>102              | -186<br>-186   | No Connec<br>A13             | 1          |
|      | 153                     | 108.3                    | -186           | A13<br>A14                   |            |
|      | 155                     | 114.6                    | -186           | No Connec                    | t l        |
|      | 156                     | 120.9                    | -186           | A15                          |            |
|      | 157                     | 127.2                    | -186           | No Connec                    | xt IIII    |
|      | 158                     | 133.5                    | -186           | RWR                          |            |
|      | 159                     | 139.8                    | -186           | No Connec                    | xt 🛛       |
|      | 160                     | 146.1                    | -186           | RRD                          |            |
|      | 161                     | 152.4                    | -186           | No Connec                    | xt 🛛       |
|      | 162                     | 158.7                    | -186           | V <sub>SQ</sub>              |            |
|      | 163                     | 165                      | -186           | V <sub>SS</sub>              |            |
|      | 164                     | 180.7                    | -170.3         | V <sub>DD</sub>              |            |
|      | 165                     | 180.7                    | -163.8         | V <sub>DQ</sub>              |            |
|      | 166                     | 180.7                    | -157.5         | No Connec                    |            |
|      | 167                     | 180.7                    | -151.2         | MEMCSO                       |            |
|      | 168                     | 180.7                    | -144.9         | No Connec                    | л –        |
|      | 169                     | 180.7                    | -138.6         | TSCTL                        |            |
|      | 170                     | 180.7                    | -132.3         | No Connec                    | л          |
|      | 171                     | 180.7                    | -126           | DMAR                         |            |
|      | 172                     | 180.7                    | -119.7         | No Connec                    |            |
|      | 173                     | 180.7                    | -113.4         | No Connec                    | л          |
|      | 174                     | 180.7                    | -107.1         | DMAG<br>No Coppos            |            |
|      | 175                     | 180.7<br>180.7           | -100.8         | No Connec                    | л          |
|      | 176<br>177              | 180.7<br>180.7           | -94.5<br>-88.2 | DMAAK<br>MEMCSI              |            |
|      | 178                     | 180.7                    | -81.9          |                              |            |
|      | 178                     | 180.7                    | -81.9          | V <sub>sq</sub><br>No Connec | *          |
|      | 180                     | 180.7                    | -69.3          | No Connec                    |            |
|      | 181                     | 180.7                    | -63            | No Connec                    |            |
|      | 182                     | 180.7                    | -56.7          |                              | <i>.</i>   |
|      | 183                     | 180.7                    | -50.4          | No Connec                    | *          |
|      | 184                     | 180.7                    | -44.1          | RD_                          |            |
|      | 185                     | 180.7                    | -37.8          | No Connec                    | *          |
|      | 186                     | 180.7                    | -31.5          | <u>CS</u>                    | л<br>—     |
|      | 187                     | 180.7                    | -25.2          | No Connec                    | *          |
|      | 188                     | 180.7                    | -18.9          | V <sub>DQ</sub>              |            |
|      | 189                     | 180.7                    | -12.6          | V <sub>ss</sub>              |            |
|      | 190                     | 180.7                    | -6.3           | V <sub>DD</sub>              |            |
|      | 191                     | 180.7                    | 0              | V <sub>SQ</sub>              |            |
|      | 192                     | 180.7                    | 6.3            | No Connec                    | xt         |
|      | 193                     | 180.7                    | 12.6           | No Connec                    |            |
|      | 194                     | 180.7                    | 18.9           | No Connec                    | xt         |
|      | 195                     | 180.7                    | 25.2           | MCLK                         |            |
|      | 196                     | 180.7                    | 31.5           | No Connec                    | xt 🛛       |
|      | 197                     | 180.7                    | 37.8           | AEN                          |            |
|      | 198                     | 180.7                    | 44.1           | No Connec                    | xt 🛛       |
|      | 199                     | 180.7                    | 50.4           | DMAGO                        |            |
|      | 200                     | 180.7                    | 56.7           | No Connec                    | rt 🛛       |
|      |                         |                          |                |                              |            |
| NOTE | : The die center is the | coordinate origin (0,0). | re B-1         |                              |            |
|      |                         | r igu                    |                |                              |            |
|      |                         |                          |                |                              |            |
|      |                         |                          |                |                              |            |
|      |                         | NDARD                    | SIZE           |                              | 5062 90577 |
|      | MICROCIRC               | CUIT DRAWING             | A              |                              | 5962-89577 |
|      |                         | CENTER COLUMBUS          |                |                              |            |
|      |                         | OHIO 43216-5000          |                | REVISION LEVEL               | SHEET      |
|      | COLUMDUS,               |                          |                | G                            | 45         |
|      |                         |                          |                |                              |            |
|      |                         |                          | 1              | 1                            | 1          |

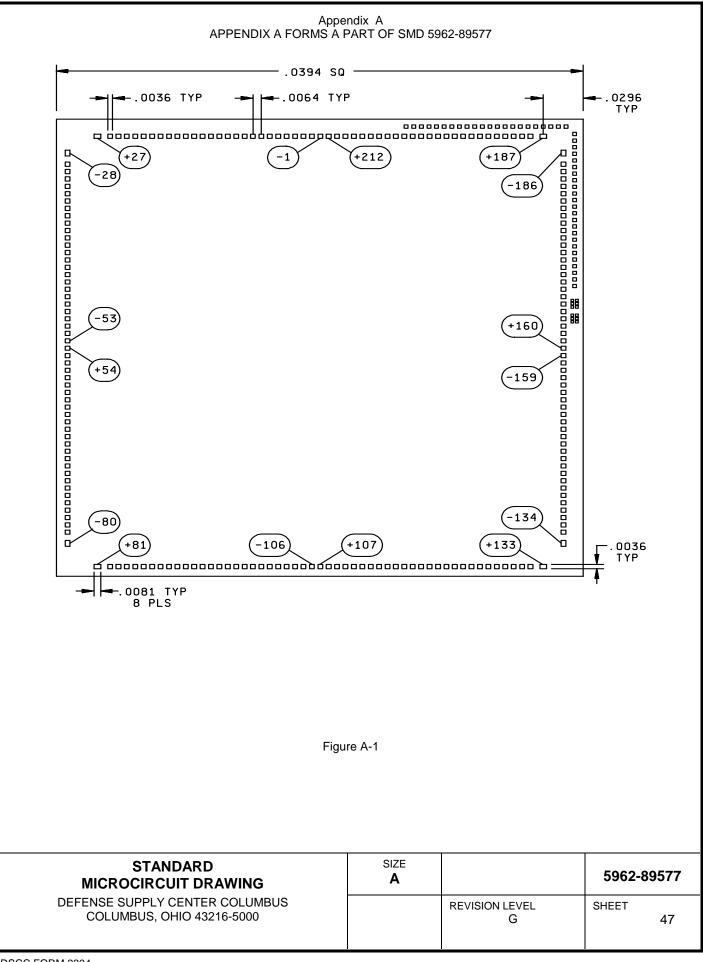
Die bonding pad locations and electrical functions

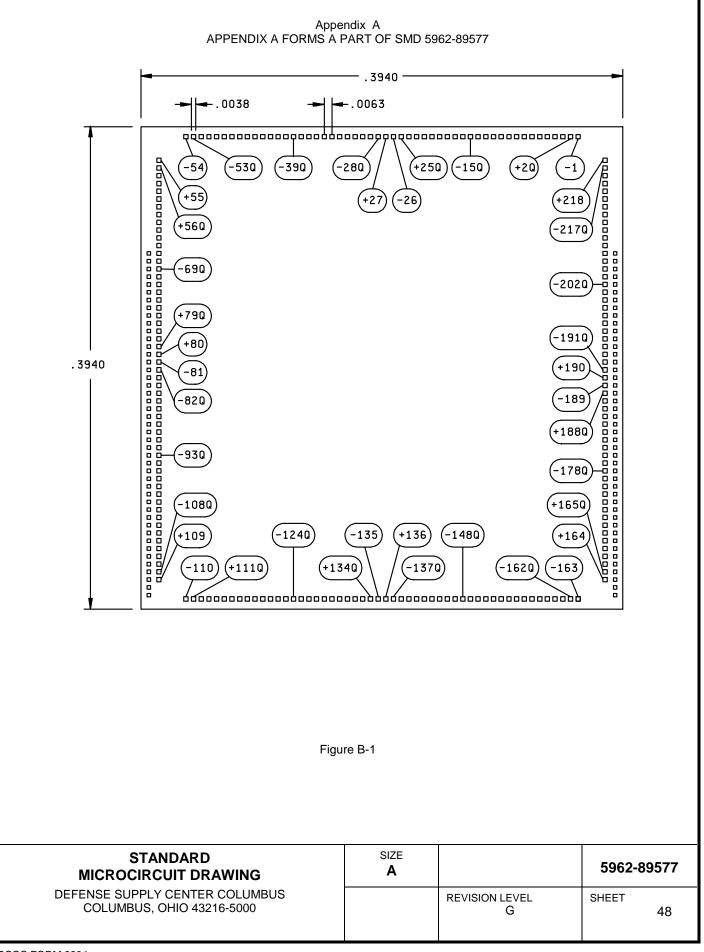
| PAD | XCENTER | YCENTER | PAD NAME        |
|-----|---------|---------|-----------------|
| 201 | 180.7   | 63      | No Connect      |
| 202 | 180.7   | 69.3    | V <sub>SQ</sub> |
| 203 | 180.7   | 75.6    | STDINT          |
| 204 | 180.7   | 81.9    | STDPUL          |
| 205 | 180.7   | 88.2    | No Connect      |
| 206 | 180.7   | 94.5    | HPINT           |
| 207 | 180.7   | 100.8   | MCKD2           |
| 208 | 180.7   | 107.1   | No Connect      |
| 209 | 180.7   | 113.4   | SSYSF           |
| 210 | 180.7   | 119.7   | No Connect      |
| 211 | 180.7   | 126     | TEST            |
| 212 | 180.7   | 132.3   | No Connect      |
| 213 | 180.7   | 138.6   | BURST           |
| 214 | 180.7   | 144.9   | No Connect      |
| 215 | 180.7   | 151.2   | No Connect      |
| 216 | 180.7   | 157.6   | No Connect      |
| 217 | 180.7   | 163.9   | V <sub>SQ</sub> |
| 218 | 180.7   | 170.2   | V <sub>DD</sub> |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         |                 |
|     |         |         |                 |

NOTE: The die center is the coordinate origin (0,0).

Figure B-1

| STANDARD<br>MICROCIRCUIT DRAWING                            | SIZE<br>A |                     | 5962-89577 |
|---|-----------|---------------------|------------|
| DEFENSE SUPPLY CENTER COLUMBUS<br>COLUMBUS, OHIO 43216-5000 |           | REVISION LEVEL<br>G | SHEET 46   |





#### STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN

#### DATE: 02-07-23

Approved sources of supply for SMD 5962-89577 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535.

| Standard<br>Microcircuit drawing<br>PIN <u>1</u> / | Vendor<br>CAGE<br>number | Vendor<br>similar<br>PIN <u>2</u> / |
|--|--------------------------|-------------------------------------|
| 5962-8957701XA                                     | 65342                    | UT1553BCRTMGA                       |
| 5962-8957701XC                                     | 65342                    | UT1553BCRTMGC                       |
| 5962-8957701YA                                     | 65342                    | UT1553BCRTMWA                       |
| 5962-8957701YC                                     | 65342                    | UT1553BCRTMWC                       |
| 5962-8957701ZA                                     | 65342                    | UT1553BCRTMAA                       |
| 5962-8957701ZC                                     | 65342                    | UT1553BCRTMAC                       |
| 5962H8957701XA                                     | 65342                    | UT1553BCRTMGAH                      |
| 5962H8957701XC                                     | 65342                    | UT1553BCRTMGCH                      |
| 5962H8957701YA                                     | 65342                    | UT1553BCRTMWAH                      |
| 5962H8957701YC                                     | 65342                    | UT1553BCRTMWCH                      |
| 5962H8957701ZA                                     | 65342                    | UT1553BCRTMAAH                      |
| 5962H8957701ZC                                     | 65342                    | UT1553BCRTMACH                      |
| 5962H8957701VXA                                    | 65342                    | UT1553BCRTMVGAH                     |
| 5962H8957701VXC                                    | 65342                    | UT1553BCRTMVGCH                     |
| 5962H8957701VYA                                    | 65342                    | UT1553BCRTMVWAH                     |
| 5962H8957701VYC                                    | 65342                    | UT1553BCRTMVWCH                     |
| 5962H8957701VZA                                    | 65342                    | UT1553BCRTMVAAH                     |
| 5962H8957701VZC                                    | 65342                    | UT1553BCRTMVACH                     |

#### STANDARD MICROCIRCUIT DRAWING SOURCE APPROVAL BULLETIN - Continued

| Standard             | Vendor     | Vendor            |
|----------------------|------------|-------------------|
| Microcircuit drawing | CAGE       | Similar           |
| PIN <u>1/</u>        | number     | PIN <u>2</u> /    |
| 5962-8957701Q9A      | 65342      | UT1553BCRTM-Q DIE |
| 5962-8957701V9A      | 65342      | UT1553BCRTM-V DIE |
| 5962H8957701Q9A      | <u>3</u> / |                   |
| 5962H8957701V9A      | <u>3</u> / |                   |
| 5962H8957701Q9B      | 65342      | UT1553BCRTM-Q DIE |
| 5962H8957701V9B      | 65342      | UT1553BCRTM-V DIE |

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the Vendor to determine its availability.
- <u>2</u>/ <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- <u>3/</u> Not available from an approved source of supply.

Vendor CAGE <u>number</u>

65342

Vendor name and address

UTMC Aeroflex Microelectronics Systems Inc. 4350 Centennial Boulevard Colorado Springs, Colorado 80907-3486

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in the information bulletin.